EVALUATION KIT AVAILABLE

MAXIM

EEPROM-Programmable, Octal/Hex/Quad, Power-Supply Sequencers/Supervisors

General Description

The MAX6889/MAX6890/MAX6891 EEPROM-configurable, multivoltage supply sequencers/supervisors monitor several voltage detector inputs and general-purpose logic inputs and feature programmable outputs for highly configurable power-supply sequencing applications. The MAX6889 features eight voltage detector inputs and ten programmable outputs. The MAX6890 features six voltage detector inputs and eight programmable outputs, while the MAX6891 features four voltage detector inputs and five programmable outputs. Manual reset and margin disable inputs offer additional flexibility.

All voltage detectors offer a configurable threshold for undervoltage detection. High-voltage input IN1 monitors voltages from 2.5V to 13.2V in 50mV increments, or from 1.25V to 7.625V in 25mV increments. Inputs IN2–IN7 monitor voltages from 1V to 5.5V in 20mV increments or from 0.5V to 3.05V in 10mV increments. High-voltage input IN8 monitors voltages from 2.5V to 15.25V in 50mV increments, or from 1.25V to 7.625V in 25mV increments.

Programmable output stages control power-supply sequencing or system resets/interrupts. Programmable output options include: active-high, active-low, open drain, and weak pullup. Programmable timing delay blocks configure each output to wait between 25µs and 1600ms before deasserting.

The MAX6889/MAX6890/MAX6891 feature a watchdog timer for added flexibility. Program the watchdog timer to assert one or more programmable outputs. The initial and normal watchdog timeout periods are independently programmable from 6.25ms to 102.4s.

An SMBus™/I²C-compatible, 2-wire serial data interface programs and communicates with the configuration EEPROM, the configuration registers, and the internal 512-bit user EEPROM.

The MAX6889/MAX6890/MAX6891 are available in 5mm x 5mm x 0.8mm thin QFN packages and are specified to operate over the extended temperature range (-40°C to +85°C).

Applications

Telecommunication/Central Office Systems

Networking Systems

Servers/Workstations

Base Stations

Storage Equipment

Multi-Microprocessor/Voltage Systems

Features

♦ **Eight (MAX6889), Six (MAX6890), or Four (MAX6891) Configurable Input Voltage Detectors**
   High-Voltage Input (1.25V to 7.625V or 2.5V to 13.2V)
   Six (MAX6889), Five (MAX6890), or Three (MAX6891) Voltage Inputs (0.5V to 3.05V or 1V to 5.5V)
   Additional (MAX6889) High-Voltage Input (1.25V to 7.625V or 2.5V to 15.25V)

♦ **Four (MAX6889/MAX6890) or Three (MAX6891) General-Purpose Logic Inputs**

♦ **Configurable Watchdog Timer**

♦ **Ten (MAX6889), Eight (MAX6890), or Five (MAX6891) Programmable Outputs**
   Active-High, Active-Low, Open Drain, Weak Pullup
   Timing Delays from 25µs to 1600ms

♦ **Margining Disable and Manual Reset Controls**

♦ **512-Bit Internal User EEPROM**
   Endurance: 100,000 Erase/Write Cycles
   Data Retention: 10 Years

♦ **I²C/SMBus-Compatible Serial Configuration/Communication Interface**

♦ **±1% Threshold Accuracy**

Ordering Information

PART	TEMP RANGE	PIN-PACKAGE
MAX6889ETJ	-40°C to +85°C	32 Thin QFN-EP*
MAX6890ETI	-40°C to +85°C	28 Thin QFN-EP*
MAX6891ETP	-40°C to +85°C	20 Thin QFN-EP*

EP = Exposed pad.

Pin Configurations and Typical Operating Circuit appear at end of data sheet.

SMBus is a trademark of Intel Corp.

MAX6889/MAX6890/MAX6891

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EEPROM-Programmable, Octal/Hex/Quad, Power-Supply Sequencers/Supervisors

ABSOLUTE MAXIMUM RATINGS

(All voltages referenced to GND.)

IN2–IN7, V_{CC}, SDA, SCL, A0, A1, GPI_
$\overline{MR}$, $\overline{MARGIN}$ ....-0.3V to +6V
IN1, PO_ ....-0.3V to +14V
IN8...-0.3V to +20V
DBP ....-0.3V to +3V
Input/Output Current (all pins)...±20mA
Continuous Power Dissipation (T_A = +70°C)
  20-Pin Thin QFN (derate 21.3mW/°C
    above +70°C)...1702mW

28-Pin Thin QFN (derate 21.3mW/°C
  above +70°C)...1702mW
32-Pin Thin QFN (derate 21.3mW/°C
  above +70°C)...1702mW
Operating Temperature Range ....-40°C to +85°C
Maximum Junction Temperature ....+150°C
Storage Temperature Range ....-65°C to +150°C
Lead Temperature (soldering, 10s) ....+300°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

(V_{IN1} = 6.5V to 13.2V, V_{IN2}–V_{IN7} = 2.7V to 5.5V, V_{IN8} = 10V, GPI_ = GND, $\overline{MARGIN}$ = $\overline{MR}$ = DBP, T_A = -40°C to +85°C, unless other-wise noted. Typical values are at T_A = +25°C.) (Notes 1, 2, 3)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Operating Voltage Range (Note 4)	V_{IN1}	Voltage on IN1 to ensure the device is fully operational, IN2–IN8 = GND	4.0		13.2	V
		Voltage on any one of IN2–IN5 or V_{CC} to ensure the device is fully operational, IN1 = GND	2.7		5.5	
IN1 Supply Voltage (Note 4)	V_{IN1P}	Minimum voltage on IN1 to guarantee that the device is powered through IN1			6.5	V
Undervoltage Lockout	V_{UVLO}	Minimum voltage on one of IN2–IN5 to guarantee the device is EEPROM configured			2.5	V
Digital Bypass Voltage	V_{DBP}	No load	2.48	2.55	2.67	V
Supply Current	I_{CC}	V_{IN1} = 13.2V, IN2–IN8 = GND, no load		1	1.2	mA
		Writing to configuration registers or EEPROM, no load		1.1	1.5	mA
Threshold Voltage Range	V_{TH}	V_{IN1} (50mV increments)	2.5		13.2	V
		V_{IN1} (25mV increments)	1.25		7.625	
		V_{IN2}–V_{IN7} (20mV increments)	1.0		5.5	
		V_{IN2}–V_{IN7} (10mV increments)	0.50		3.05	
		V_{IN8} (50mV increments)	2.50		15.25	
		V_{IN8} (25mV increments)	1.250		7.625	
		V_{IN2}–V_{IN8} (high-Z mode in 3.3mV increments)	0.167		1.017	

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ELECTRICAL CHARACTERISTICS (continued)

(V_{IN1} = 6.5V to 13.2V, V_{IN2}–V_{IN7} = 2.7V to 5.5V, V_{IN8} = 10V, GPI_ = GND, $\overline{MARGIN}$ = $\overline{MR}$ = DBP, T_A = -40°C to +85°C, unless otherwise noted. Typical values are at T_A = +25°C.) (Notes 1, 2, 3)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
IN2–IN7 Threshold Accuracy		T_A = +25°C to +85°C ($V_{IN\_}$ falling)	$V_{IN\_}$ = 2.5V to 5.5V (20mV increments)	-1		+1	%
			$V_{IN\_}$ = 1V to 2.5V (20mV increments)	-25		+25	mV
			$V_{IN\_}$ = 1.25V to 3.05V (10mV increments)	-1		+1	%
			$V_{IN\_}$ = 0.5V to 1.25V (10mV increments)	-12.5		+12.5	mV
		T_A = -40°C to +85°C ($V_{IN\_}$ falling)	$V_{IN\_}$ = 2.5V to 5.5V (20mV increments)	-2		+2	%
			$V_{IN\_}$ = 1V to 2.5V (20mV increments)	-50		+50	mV
			$V_{IN\_}$ = 1.25V to 3.05V (10mV increments)	-2		+2	%
			$V_{IN\_}$ = 0.5V to 1.25V (10mV increments)	-25		+25	mV
IN1/IN8 Threshold Accuracy		T_A = +25°C to +85°C ($V_{IN\_}$ falling)	$V_{IN\_}$ = 6.25V to 13.2V (6.25V to 15.25V for IN8) (50mV increments)	-1		+1	%
			$V_{IN\_}$ = 2.5V to 6.25V (50mV increments)	-62.5		+62.5	mV
			$V_{IN\_}$ = 3.125V to 7.625V (25mV increments)	-1		+1	%
			$V_{IN\_}$ = 1.25V to 3.125V (25mV increments)	-31.25		+31.25	mV
		T_A = -40°C to +85°C ($V_{IN\_}$ falling)	$V_{IN\_}$ = 6.25V to 13.2V (6.25V to 15.25V for IN8) (50mV increments)	-2		+2	%
			$V_{IN\_}$ = 2.5V to 6.25V (50mV increments)	-125		+125	mV
			$V_{IN\_}$ = 3.125V to 7.625V (25mV increments)	-2		+2	%
			$V_{IN\_}$ = 1.25V to 3.125V (25mV increments)	-62.5		+62.5	mV
IN_ Threshold Accuracy		IN_ = 0.6V in high-Z mode ($V_{IN\_}$ falling)	T_A = +25°C to +85°C	-1		+1	%
			T_A = -40°C to 85°C	-2		+2	
Threshold Hysteresis	$V_{TH\text{-}HYST}$				0.3		% V_{TH}

ELECTRICAL CHARACTERISTICS (continued)

(V_{IN1} = 6.5V to 13.2V, V_{IN2}–V_{IN7} = 2.7V to 5.5V, V_{IN8} = 10V, GPI_ = GND, $\overline{MARGIN}$ = $\overline{MR}$ = DBP, T_A = -40°C to +85°C, unless other-wise noted. Typical values are at T_A = +25°C.) (Notes 1, 2, 3)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
Reset-Threshold Temperature Coefficient	ΔV_{TH}/°C				10		ppm/°C
Threshold-Voltage Differential Nonlinearity	V_{TH} DNL			-1		+1	LSB
IN1 Input Leakage Current	I_{LIN1}	For V_{IN1} < the highest of V_{IN2}–V_{IN5}			100	140	µA
IN2–IN7 Input Impedance	R_{IN2} to R_{IN7}	V_{IN1} > 6.5V		290	400	555	kΩ
IN8 Input Impedance	R_{IN8}			730	1000	1400	kΩ
IN2–IN8 Input Leakage Current	$I_{LIN2\text{-}LIN8}$	IN2–IN8 in high-Z mode, $V_{IN\_}$ = 1.017V		-50		+50	nA
Power-Up Delay	t_{PU}	$V_{CC} \geq V_{UVLO}$				3	ms
IN_ to PO_ Delay	t_{DPO}	$V_{IN\_}$ falling or rising, 100mV overdrive			20		µs
PO_ Timeout Period	t_{RP}	Register contents (Table 19)	000	8	25	80	µs
			001	1.406	1.5625	1.719	ms
			010	5.625	6.25	6.875	
			011	22.5	25	27.5	
			100	45	50	55	
			101	180	200	220	
			110	360	400	440	
			111	1440	1600	1760	
PO_ Output Low	V_{OL}	I_{SINK} = 4mA, output asserted				0.4	V
PO_ Output Initial Pulldown Current	I_{PD}	$V_{CC} \leq V_{UVLO}$, V_{PO} = 0.8V			10	40	µA
PO_ Output Open-Drain Leakage Current	I_{LKG}	Output high impedance		-1		+1	µA
PO_ Output Pullup Resistance	R_{PU}	$V_{PO\_}$ = 2V		6.6	10	15.0	kΩ
$\overline{MR}$, $\overline{MARGIN}$, GPI_ Input Voltage	V_{IL}					0.6	V
	V_{IH}			1.4			
$\overline{MR}$ Input Pulse Width	t_{MR}			1			µs
$\overline{MR}$ Glitch Rejection					100		ns
$\overline{MR}$ to PO_ Delay	t_{DMR}				2		µs
$\overline{MR}$ to DBP Pullup Current	I_{MR}	$V_{\overline{MR}}$ = 1.4V		5	10	15	µA
$\overline{MARGIN}$ to DBP Pullup Current	I_{MARGIN}	$V_{\overline{MARGIN}}$ = 1.4V		5	10	15	µA
GPI_ Input Hysteresis					100		mV
GPI_ to PO_ Delay	$t_{DGPI\_}$				200		ns
GPI_ Pulldown Current	$I_{GPI\_}$	$V_{GPI\_}$ = 0.6V		5	10	15	µA
Watchdog Input Pulse Width	t_{WDI}	GPI_ configured as a watchdog input		50			ns

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ELECTRICAL CHARACTERISTICS (continued)

(V_{IN1} = 6.5V to 13.2V, V_{IN2}–V_{IN7} = 2.7V to 5.5V, V_{IN8} = 10V, GPI_ = GND, $\overline{MARGIN}$ = $\overline{MR}$ = DBP, T_A = -40°C to +85°C, unless otherwise noted. Typical values are at T_A = +25°C.) (Notes 1, 2, 3)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
Watchdog Timeout Period	t_{WD}	Register contents (Table 21)	000	5.625	6.25	6.875	ms
			001	22.5	25	27.5	
			010	90	100	110	
			011	360	400	440	
			100	1.44	1.60	1.76	s
			101	5.76	6.40	7.04	
			110	23.04	25.60	28.16	
			111	92.16	102.40	112.64	
SERIAL INTERFACE LOGIC (SDA, SCL, A0, A1)							
Logic-Input Low Voltage	V_{IL}					0.8	V
Logic-Input High Voltage	V_{IH}			2.0			V
Input Leakage Current	I_{LKG}			-1		+1	µA
Output Low Voltage	V_{OL}	I_{SINK} = 3mA				0.4	V
Input/Output Capacitance	$C_{I/O}$				10		pF

SERIAL INTERFACE TIMING CHARACTERISTICS (Figure 3)

(IN1 = GND, V_{IN2}–V_{IN7} = 2.7V to 5.5V, V_{IN8} = 10V, GPI_ = GND, $\overline{MARGIN}$ = $\overline{MR}$ = DBP, T_A = -40°C to +85°C, unless otherwise noted. Typical values are at T_A = +25°C.) (Notes 1, 2, 3)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Serial Clock Frequency	f_{SCL}				400	kHz
Clock Low Period	t_{LOW}		1.3			µs
Clock High Period	t_{HIGH}		0.6			µs
Bus-Free Time	t_{BUF}		1.3			µs
START Setup Time	$t_{SU:STA}$		0.6			µs
START Hold Time	$t_{HD:STA}$		0.6			µs
STOP Setup Time	$t_{SU:STO}$		0.6			µs
Data In Setup Time	$t_{SU:DAT}$		100			ns
Data In Hold Time	$t_{HD:DAT}$		30		900	ns
Receive SCL/SDA Minimum Rise Time	t_R	(Note 5)		20 + 0.1 x C_{BUS}		ns
Receive SCL/SDA Maximum Rise Time	t_R	(Note 5)		300		ns
Receive SCL/SDA Minimum Fall Time	t_F	(Note 5)		20 + 0.1 x C_{BUS}		ns
Receive SCL/SDA Maximum Fall Time	t_F	(Note 5)		300		ns
Transmit SDA Fall Time	t_F	C_{BUS} = 400pF	20 + 0.04 x C_{BUS}		300	ns

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SERIAL INTERFACE TIMING CHARACTERISTICS (Figure 3) (continued)

(IN1 = GND, V_{IN2}–V_{IN7} = 2.7V to 5.5V, V_{IN8} = 10V, GPI_ = GND, $\overline{MARGIN}$ = $\overline{MR}$ = DBP, T_A = -40°C to +85°C, unless otherwise noted. Typical values are at T_A = +25°C.) (Notes 1, 2, 3)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Pulse Width of Spike Suppressed	t_{SP}	(Note 6)		50		ns
EEPROM Byte Write Cycle Time	t_{WR}	(Note 7)			11	ms

Note 1: 100% production tested at T_A = +25°C and T_A = +85°C. Specifications at T_A = -40°C are guaranteed by design.
Note 2: Specifications are guaranteed for the stated global conditions. The device also meets the parameters specified when 0 < V_{IN1} < 6.5V and at least one of V_{IN2}–V_{IN5} is between 2.7V and 5.5V, while the remaining V_{IN2}–V_{IN5} are between 0 and 5.5V. Specifications are also guaranteed if V_{CC} is externally supplied.
Note 3: Device may be supplied from any one of IN1 to IN5, or V_{CC} (see the *Powering the MAX6889/MAX6890/MAX6891* section).
Note 4: The internal supply voltage, measured at V_{CC}, equals the maximum of IN2 to IN5 if V_{IN1} = 0V, or equals 5.4V if V_{IN1} > 6.5V. For 4V < V_{IN1} < 6.5V and V_{IN2}–V_{IN5} > 2.7V, the input that powers the device cannot be determined.
Note 5: C_{BUS} = total capacitance of one bus line in pF. Rise and fall times are measured between 0.1 x V_{BUS} and 0.9 x V_{BUS}.
Note 6: Input filters on SDA, SCL, A0, and A1 suppress noise spikes < 50ns.
Note 7: An additional cycle is required when writing to configuration memory for the first time.
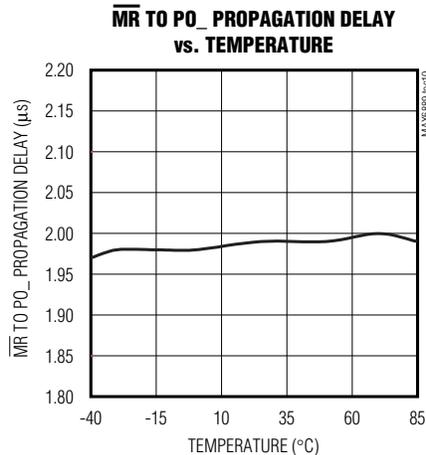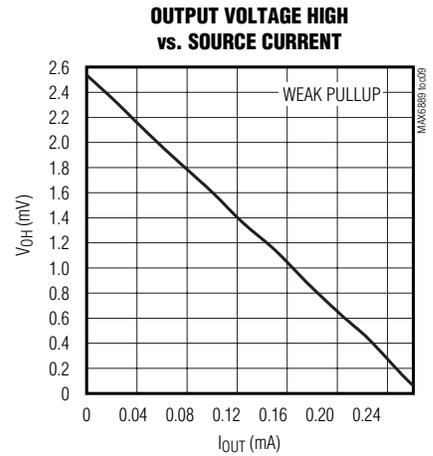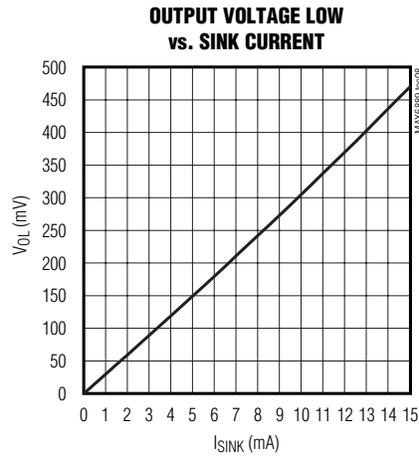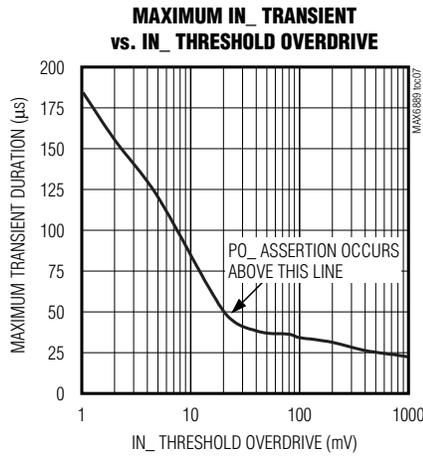
Typical Operating Characteristics

(V_{IN1} = 6.5V to 13.2V, V_{IN8} = 10V, $V_{IN\_}$ = 2.7V to 5.5V, GPI_ = GND, $\overline{MARGIN}$ = $\overline{MR}$ = DBP, T_A = +25°C, unless otherwise noted.)

SUPPLY CURRENT vs. SUPPLY VOLTAGE (IN1)

SUPPLY CURRENT vs. SUPPLY VOLTAGE (IN2–IN5)

NORMALIZED PO_ TIMEOUT PERIOD vs. TEMPERATURE

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Typical Operating Characteristics (continued)

(V_{IN1} = 6.5V to 13.2V, V_{IN8} = 10V, $V_{IN\_}$ = 2.7V to 5.5V, GPI_ = GND, $\overline{MARGIN}$ = $\overline{MR}$ = DBP, T_A = +25°C, unless otherwise noted.)

IN_ TO PO_ PROPAGATION DELAY vs. TEMPERATURE

NORMALIZED WATCHDOG TIMEOUT PERIOD vs. TEMPERATURE

NORMALIZED IN_ THRESHOLD vs. TEMPERATURE

MAXIMUM IN_ TRANSIENT vs. IN_ THRESHOLD OVERDRIVE

OUTPUT VOLTAGE LOW vs. SINK CURRENT

OUTPUT VOLTAGE HIGH vs. SOURCE CURRENT

$\overline{MR}$ TO PO_ PROPAGATION DELAY vs. TEMPERATURE

MAX6889/MAX6890/MAX6891
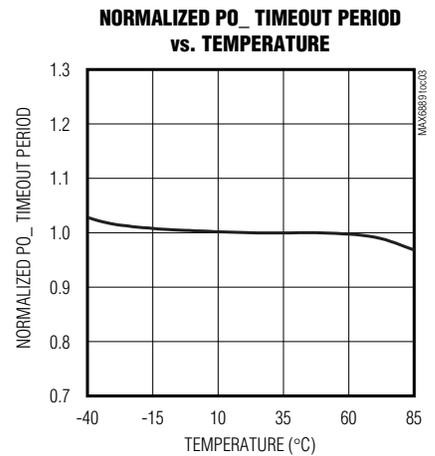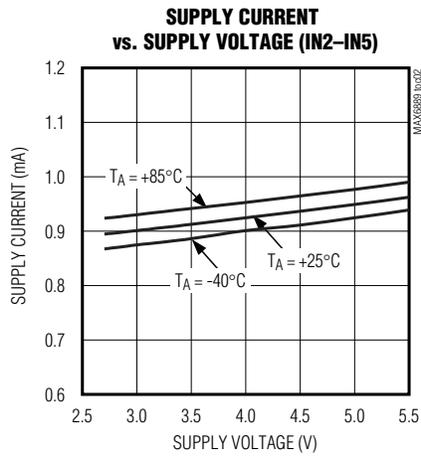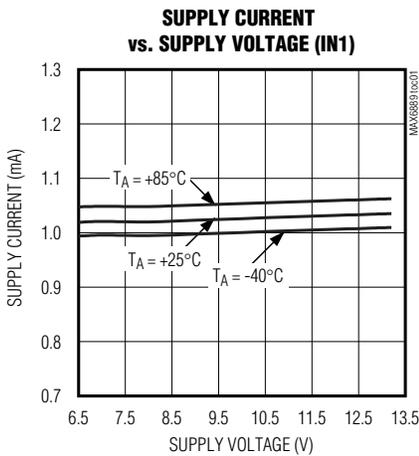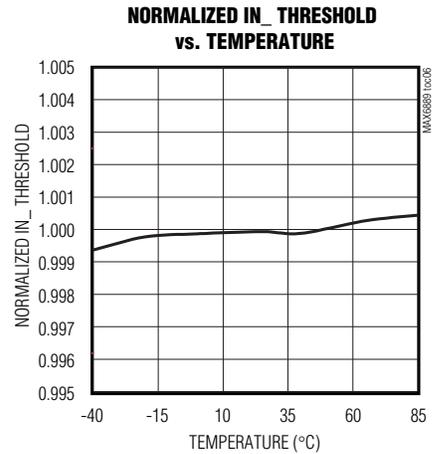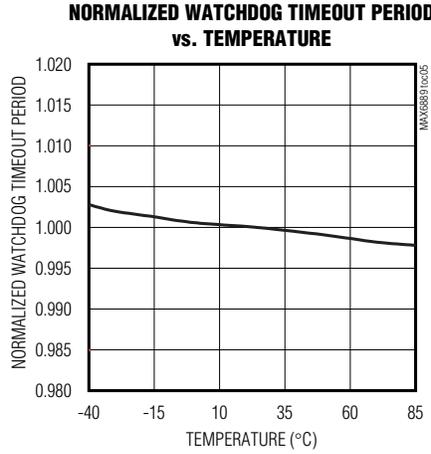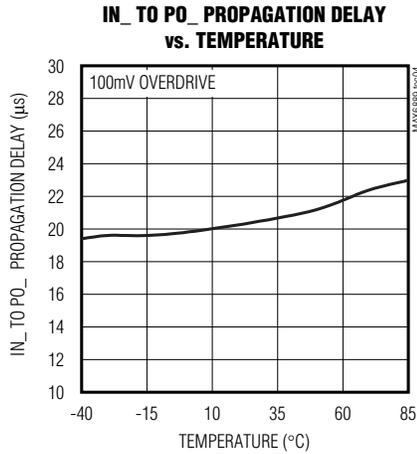
Pin Description

PIN			NAME	FUNCTION
MAX6889	MAX6890	MAX6891		
1	1	1	PO2	Programmable Output 2. Configurable, active-high, active-low, open-drain, or weak pullup output. PO2 pulls low with a 10µA internal current sink for 1V < V_{CC} < V_{UVLO}. PO2 assumes its programmed conditional output state when V_{CC} exceeds undervoltage lockout (UVLO) of 2.5V.
2	2	2	PO3	Programmable Output 3. Configurable, active-high, active-low, open-drain, or weak pullup output. PO3 pulls low with a 10µA internal current sink for 1V < V_{CC} < V_{UVLO}. PO3 assumes its programmed conditional output state when V_{CC} exceeds undervoltage lockout (UVLO) of 2.5V.
3	3	3	PO4	Programmable Output 4. Configurable, active-high, active-low, open-drain, or weak pullup output. PO4 pulls low with a 10µA internal current sink for 1V < V_{CC} < V_{UVLO}. PO4 assumes its programmed conditional output state when V_{CC} exceeds undervoltage lockout (UVLO) of 2.5V.
4	4	4	GND	Ground
5	5	5	PO5	Programmable Output 5. Configurable, active-high, active-low, open-drain, or weak pullup output. PO5 pulls low with a 10µA internal current sink for 1V < V_{CC} < V_{UVLO}. PO5 assumes its programmed conditional output state when V_{CC} exceeds undervoltage lockout (UVLO) of 2.5V.
6	6	—	PO6	Programmable Output 6. Configurable, active-high, active-low, open-drain, or weak pullup output. PO6 pulls low with a 10µA internal current sink for 1V < V_{CC} < V_{UVLO}. PO6 assumes its programmed conditional output state when V_{CC} exceeds undervoltage lockout (UVLO) of 2.5V.
7	7	—	PO7	Programmable Output 7. Configurable, active-high, active-low, open-drain, or weak pullup output. PO7 pulls low with a 10µA internal current sink for 1V < V_{CC} < V_{UVLO}. PO7 assumes its programmed conditional output state when V_{CC} exceeds undervoltage lockout (UVLO) of 2.5V.
8	8	—	PO8	Programmable Output 8. Configurable, active-high, active-low, open-drain, or weak pullup output. PO8 pulls low with a 10µA internal current sink for 1V < V_{CC} < V_{UVLO}. PO8 assumes its programmed conditional output state when V_{CC} exceeds undervoltage lockout (UVLO) of 2.5V.
9	—	—	PO9	Programmable Output 9. Configurable, active-high, active-low, open-drain, or weak pullup output. PO9 pulls low with a 10µA internal current sink for +1V < V_{CC} < V_{UVLO}. PO9 assumes its programmed conditional output state when V_{CC} exceeds undervoltage lockout (UVLO) of 2.5V.
10	—	—	PO10	Programmable Output 10. Configurable, active-high, active-low, open-drain, or weak pullup output. PO10 pulls low with a 10µA internal current sink for 1V < V_{CC} < V_{UVLO}. PO10 assumes its programmed conditional output state when V_{CC} exceeds undervoltage lockout (UVLO) of 2.5V.
11	9	6	$\overline{\text{MARGIN}}$	Margin Input. $\overline{\text{MARGIN}}$ holds PO_ in its existing state when $\overline{\text{MARGIN}}$ is driven low. Leave $\overline{\text{MARGIN}}$ unconnected or connect to DBP if unused. $\overline{\text{MARGIN}}$ overrides $\overline{\text{MR}}$ if both assert at the same time. $\overline{\text{MARGIN}}$ is internally pulled up to DBP through a 10µA current source.

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Pin Description (continued)

PIN			NAME	FUNCTION
MAX6889	MAX6890	MAX6891		
12	10	7	$\overline{MR}$	Manual Reset Input. $\overline{MR}$ is configurable to either assert PO_ into a programmed state or to have no effect on PO_ when driving $\overline{MR}$ low (see Table 6). Leave $\overline{MR}$ unconnected or connect to DBP if unused. $\overline{MR}$ is internally pulled up to DBP through a 10µA current source.
13	11	8	SDA	Serial Data Input/Output (Open Drain). SDA requires an external pullup resistor.
14	12	9	SCL	Serial Clock Input. SCL requires an external pullup resistor.
15	13	10	A0	Address Input 0. Address inputs allow up to four (MAX6889/MAX6890) or two (MAX6891) connections on one common bus. Connect A0 to GND or to the serial-interface power supply.
16	14	—	A1	Address Input 1. Address inputs allow up to four MAX6889/MAX6890 connections on one common bus. Connect A1 to GND or to the serial-interface power supply.
17	15	—	GPI4	General-Purpose Logic Input 4. An internal 10µA current source pulls GPI4 to GND. Configure GPI4 to control watchdog timer functions or the programmable outputs.
18	16	11	GPI3	General-Purpose Logic Input 3. An internal 10µA current source pulls GPI3 to GND. Configure GPI3 to control watchdog timer functions or the programmable outputs.
19	17	12	GPI2	General-Purpose Logic Input 2. An internal 10µA current source pulls GPI2 to GND. Configure GPI2 to control watchdog timer functions or the programmable outputs.
20	18	13	GPI1	General-Purpose Logic Input 1. An internal 10µA current source pulls GPI1 to GND. Configure GPI1 to control watchdog timer functions or the programmable outputs.
21	19	14	V_{CC}	Internal Power-Supply Voltage. Bypass V_{CC} to GND with a 1µF ceramic capacitor. V_{CC} supplies power to the internal circuitry. V_{CC} is internally powered from the highest of the monitored IN1–IN5 voltages. Do not use V_{CC} to supply power to external circuitry. To externally supply V_{CC}, see the *Powering the MAX6889/MAX6890/MAX6891* section.
22	20	15	DBP	Internal Digital Power-Supply Voltage. Bypass DBP to GND with a 1µF ceramic capacitor. DBP supplies power to the EEPROM memory, the internal logic circuitry, and the programmable outputs. Do not use DBP to supply power to external circuitry.
23	—	—	IN8	High-Voltage Input 8. Configure IN8 to detect voltage thresholds from 2.5V to 15.25V in 50mV increments, or 1.25V to 7.625V in 25mV increments. For improved noise immunity, bypass IN8 to GND with a 0.1µF capacitor installed as close to the device as possible.
24	—	—	IN7	Voltage Input 7. Configure IN7 to detect voltage thresholds between 1V and 5.5V in 20mV increments, or 0.5V to 3.05V in 10mV increments. For improved noise immunity, bypass IN7 to GND with a 0.1µF capacitor installed as close to the device as possible.

PIN			NAME	FUNCTION
MAX6889	MAX6890	MAX6891		
25	21	—	IN6	Voltage Input 6. Configure IN6 to detect voltage thresholds between 1V and 5.5V in 20mV increments, or 0.5V to 3.05V in 10mV increments. For improved noise immunity, bypass IN6 to GND with a 0.1µF capacitor installed as close to the device as possible.
26	22	—	IN5	Voltage Input 5. Configure IN5 to detect voltage thresholds between 1V and 5.5V in 20mV increments, or 0.5V to 3.05V in 10mV increments. For improved noise immunity, bypass IN5 to GND with a 0.1µF capacitor installed as close to the device as possible.
27	23	16	IN4	Voltage Input 4. Configure IN4 to detect voltage thresholds between 1V and 5.5V in 20mV increments, or 0.5V to 3.05V in 10mV increments. For improved noise immunity, bypass IN4 to GND with a 0.1µF capacitor installed as close to the device as possible.
28	24	17	IN3	Voltage Input 3. Configure IN3 to detect voltage thresholds between 1V and 5.5V in 20mV increments, or 0.5V to 3.05V in 10mV increments. For improved noise immunity, bypass IN3 to GND with a 0.1µF capacitor installed as close to the device as possible.
29	25	18	IN2	Voltage Input 2. Configure IN2 to detect voltage thresholds between 1V and 5.5V in 20mV increments, or 0.5V to 3.05V in 10mV increments. For improved noise immunity, bypass IN2 to GND with a 0.1µF capacitor installed as close to the device as possible.
30	26	19	IN1	High-Voltage Input 1. Configure IN1 to detect voltage thresholds from 2.5V to 13.2V in 50mV increments, or 1.25V to 7.625V in 25mV increments. For improved noise immunity, bypass IN1 to GND with a 0.1µF capacitor installed as close to the device as possible.
31	27	—	N.C.	No Connection. Not internally connected.
32	28	20	PO1	Programmable Output 1. Configurable, active-high, active-low, open-drain, or weak pullup output. PO1 pulls low with a 10µA internal current sink for $1V < V_{CC} < V_{UVLO}$. PO1 assumes its programmed conditional output state when V_{CC} exceeds undervoltage lockout (UVLO) of 2.5V.
EP	EP	EP	GND	Exposed Paddle. Internally connected to GND. Connect exposed paddle to GND or leave floating.

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Functional Diagram

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* FOR MAX6889/MAX6890 ONLY.
** FOR MAX6889 ONLY.
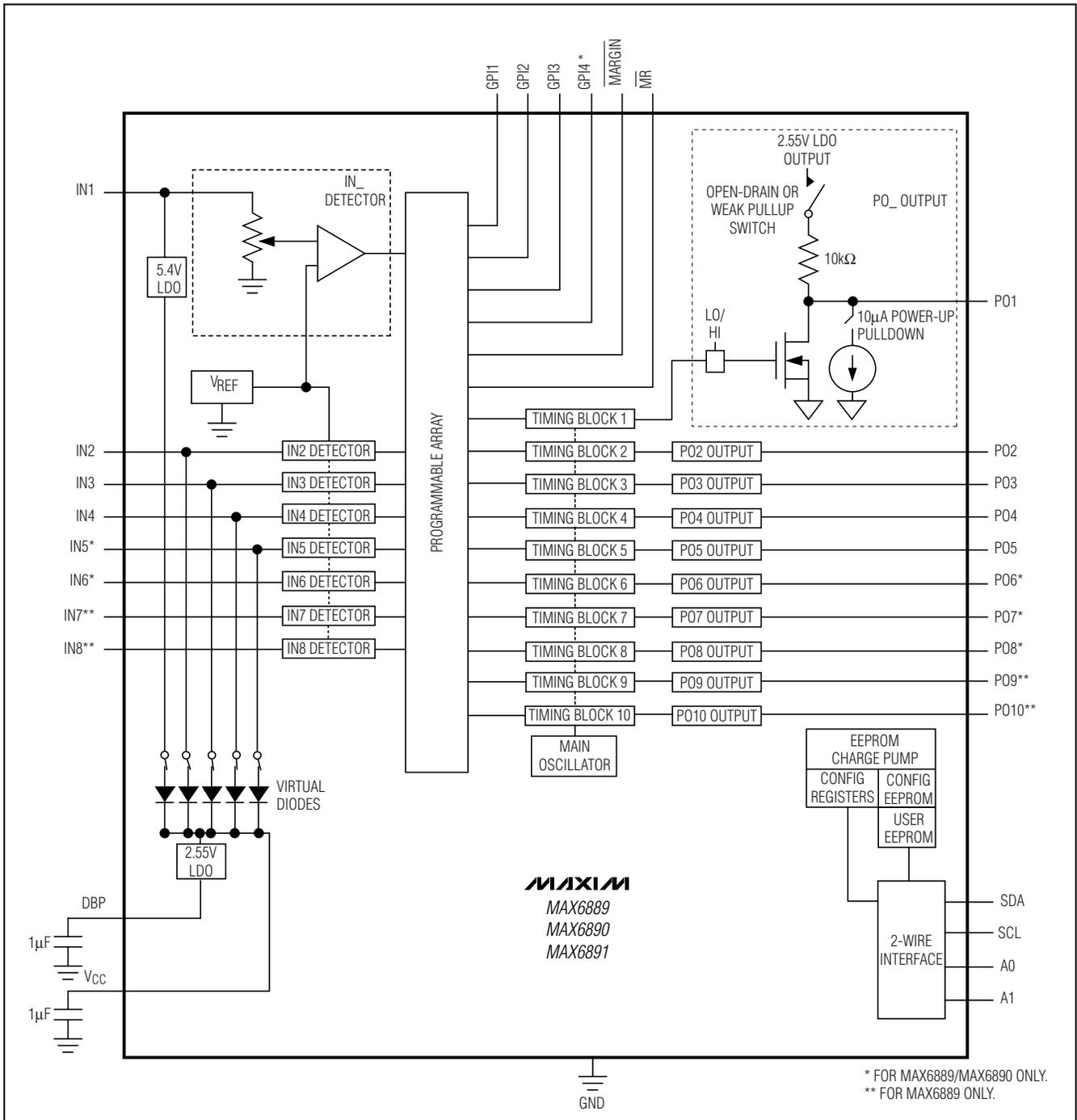
EEPROM-Programmable, Octal/Hex/Quad, Power-Supply Sequencers/Supervisors
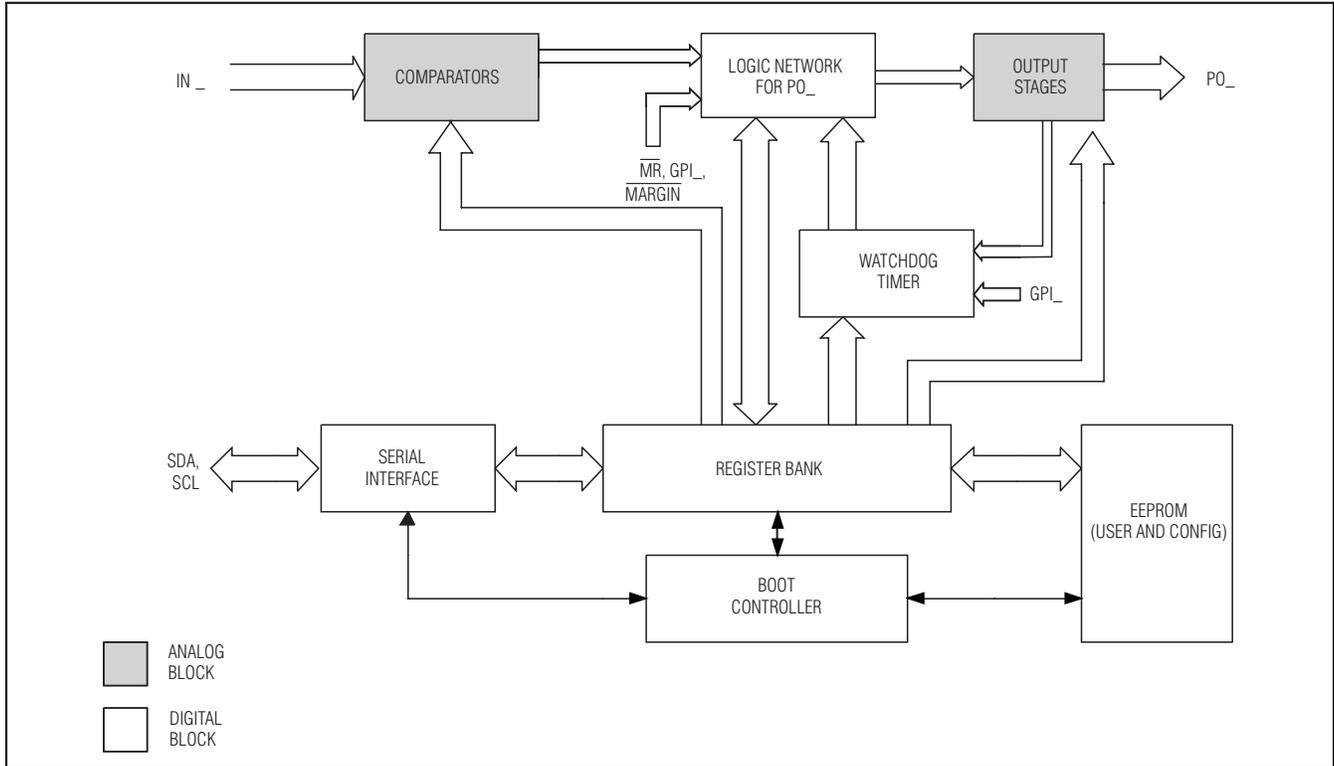

Figure 1. Top-Level Block Diagram

Detailed Description

The MAX6889/MAX6890/MAX6891 EEPROM-configurable, multivoltage supply sequencers/supervisors monitor several voltage detector inputs and general-purpose logic inputs, and feature programmable outputs for highly-configurable power-supply sequencing applications. The MAX6889 features eight voltage detector inputs and ten programmable outputs. The MAX6890 features six voltage detector inputs and eight programmable outputs, while the MAX6891 features four voltage detector inputs and five programmable outputs. Manual reset and margin disable inputs simplify board-level testing during the manufacturing process.

All voltage detectors provide configurable thresholds for undervoltage detection. The high-voltage input (IN1) monitors voltages from 1.25V to 7.625V in 25mV increments, or 2.5V to 13.2V in 50mV increments. Inputs (IN2–IN7) monitor voltages from 0.5V to 3.05V in 10mV increments, or 1.0V to 5.5V in 20mV increments. An additional high-voltage input (IN8, MAX6889 only) monitors voltages from 1.25V to 7.625V in 25mV increments, or 2.5V to 15.25V in 50mV increments. To

monitor thresholds from 0.1667V to 1.0167V in 3.3mV increments, the respective input voltage detector must be programmed for high impedance (high-Z) and an external voltage-divider must be connected.

The host controller communicates with the MAX6889/MAX6890/MAX6891s' internal 512-bit user EEPROM, configuration EEPROM, and configuration registers through an SMBus/I^{2}C-compatible serial interface (see Figure 1).

Programmable output options include active-high, active-low, open drain, and weak pullup. Program each output to assert on any voltage detector input, general-purpose logic input, watchdog timer, or manual reset. Programmable timing delay blocks configure each output to wait between 25µs and 1600ms before deasserting.

The MAX6889/MAX6890/MAX6891 feature a watchdog timer for added flexibility. Program the watchdog timer to assert one or more programmable outputs. Program the watchdog timer to clear on a combination of one GPI_ input and one programmable output, one of the GPI_ inputs only, or one of the programmable outputs only. The initial and normal watchdog timeout periods are independently programmable from 6.25ms to 102.4s.

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Table 1. Programmable Features

FEATURE	DESCRIPTION
High-Voltage Input IN1	• 2.5V to 13.2V threshold in 50mV increments. • 1.25V to 7.625V threshold in 25mV increments.
Positive Voltage Input IN2–IN7 (MAX6889) IN2–IN6 (MAX6890) IN2–IN4 (MAX6891)	• 1V to 5.5V threshold in 20mV increments. • 0.5V to 3.05V threshold in 10mV increments. • 0.1667V to 1.0167V threshold in 3.3mV increments in high-Z mode.
High-Voltage Input IN8 (MAX6889)	• 2.5V to 15.25V threshold in 50mV increments. • 1.25V to 7.625V threshold in 25mV increments. • 0.1667V to 1.0167V threshold in 3.3mV increments in high-Z mode.
Programmable Outputs PO1–PO10 (MAX6889) PO1–PO8 (MAX6890) PO1–PO5 (MAX6891)	• Active-high or active-low. • Open-drain or weak pullup output. • Dependent on $\overline{MR}$, $\overline{MARGIN}$, IN_, GPI_, and WD. • Programmable reset timeout periods of 25µs, 1.5625ms, 6.25ms, 25ms, 50ms, 200ms, 400ms, or 1.6s.
General-Purpose Logic Inputs: GPI1–GPI4 (MAX6889–MAX6890) GPI1–GPI3 (MAX6891)	• Active-high or active-low logic levels. • Configure GPI_ as inputs to the watchdog timer or the programmable output stages.
Watchdog Timer	• Clear dependent on any combination of one GPI_ input and one programmable output, a GPI_ input only, or a programmable output only. • Initial watchdog timeout period of 6.25ms, 25ms, 100ms, 400ms, 1.6s, 6.4s, 25.6s, or 102.4s. • Normal watchdog timeout period of 6.25ms, 25ms, 100ms, 400ms, 1.6s, 6.4s, 25.6s, or 102.4s. • Watchdog enable/disable.
Manual Reset Input ($\overline{MR}$)	• Forces PO_ into the active output state when $\overline{MR}$ = GND. • PO_ deassert after $\overline{MR}$ releases high and the PO_ timeout period expires.
V_{CC} Power Mode	Programs whether the device is powered from the highest IN_ input or from an external supply connected to V_{CC}.
Write Disable	Locks user EEPROM based on PO_.
Configuration Lock	Locks configuration registers and EEPROM.

Powering the MAX6889/MAX6890/MAX6891

The MAX6889/MAX6890/MAX6891 derive power from the voltage detector inputs: IN1–IN5 (MAX6889/MAX6890), IN1–IN4 (MAX6891), or an external V_{CC} supply. A virtual diode-ORing scheme selects the positive input that supplies power to the device (see the *Functional Diagram*). IN1 must be at least 4V, or one of IN2–IN5 (MAX6889/MAX6890)/IN2–IN4 (MAX6891) must be at least 2.7V to ensure device operation. An internal LDO regulates IN1 down to 5.4V.

The highest input voltage on IN2–IN5 (MAX6889/MAX6890)/IN2–IN4 (MAX6891) supplies power to the device, unless V_{IN1} > 6.5V, in which case IN1 supplies power to the device. For 4V < V_{IN1} < 6.5V and one of

V_{IN2}–V_{IN5} > 2.7V, the input power source cannot be determined due to the dropout voltage of the LDO. Internal hysteresis ensures that the supply input that initially powered the device continues to power the device when multiple input voltages are within 50mV of each other.

V_{CC} powers the analog circuitry. Bypass V_{CC} to GND with a 1µF ceramic capacitor installed as close to the device as possible. The internal supply voltage, measured at V_{CC}, equals the maximum of IN2–IN5 if V_{IN1} = 0V, or equals 5.4V when V_{IN1} > 6.5V. Do not use the internally generated V_{CC} to provide power to external circuitry. Power cannot be supplied through high-impedance voltage detector inputs. To externally supply power through V_{CC}:

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1) Apply a voltage between 2.7V and 5.5V to one of V_{CC} or IN2–IN5.

2) Program the internal/external V_{CC} power EEPROM at AEh, Bit[2] = 1 (see Table 22).

3) Power down the device.

Subsequent power-ups and software reboots require an externally supplied V_{CC} to ensure the device is fully operational.

The MAX6889/MAX6890/MAX6891 also generate a digital supply voltage (DBP) for the internal logic circuitry and the EEPROM. Bypass DBP to GND with a 1μF ceramic capacitor installed as close to the device as possible. The nominal DBP output voltage is 2.55V. Do not use DBP to provide power to external circuitry.

Inputs

The MAX6889/MAX6890/MAX6891 contain multiple logic and voltage detector inputs. Each voltage detector input is monitored for undervoltage thresholds. Table 1 summarizes these various inputs. Set the threshold voltage for each voltage detector input with registers 00h–07h. Each threshold voltage is an undervoltage threshold. Set the threshold range for each voltage detector with register 08h.

High-Voltage Input (IN1)

IN1 offers threshold voltages of 2.5V to 13.2V in 50mV increments, or 1.25V to 7.625V in 25mV increments. Use the following equations to set the threshold voltages for IN1:

$$x = \frac{V_{TH} - 2.5V}{0.05V} \text{ for 2.5V to 13.2V range}$$

$$x = \frac{V_{TH} - 1.25V}{0.025V} \text{ for 1.25V to 7.625V range}$$

where V_{TH} is the desired threshold voltage and x is the decimal code for the desired threshold (Table 2). For the 2.5V to 13.2V range, x must equal 214 or less; oth-

erwise the threshold exceeds the maximum operating voltage of IN1.

IN2–IN7

The IN2–IN7 positive voltage detectors monitor voltages from 1V to 5.5V in 20mV increments, 0.5V to 3.05V in 10mV increments, or 0.1667V to 1.0167V in 3.3mV increments in high-Z mode. Use the following equations to set the threshold voltages for IN_:

$$x = \frac{V_{TH} - 1V}{0.02V} \text{ for 1V to 5.5V range}$$

$$x = \frac{V_{TH} - 0.5V}{0.1V} \text{ for 0.5V to 3.05V range}$$

$$x = \frac{V_{TH} - 0.1667V}{0.0033V} \text{ for 0.1667V to 1.0167V high-Z range}$$

where V_{TH} is the desired threshold voltage and x is the decimal code for the desired threshold (Table 3). For the 1V to 5.5V range, x must equal 225 or less; otherwise the threshold exceeds the maximum operating voltage of IN2–IN7.

High-Voltage Input (IN8)

Configure IN8 to detect positive thresholds from 2.5V to 15.25V in 50mV increments, 1.25V to 7.625V in 25mV increments, or 0.1667V to 1.0167V in 3.3mV increments in high-Z mode. Use the following equations to set the threshold voltages for IN8:

$$x = \frac{V_{TH} - 2.5V}{0.05V} \text{ for 2.5V to 15.25V range}$$

$$x = \frac{V_{TH} - 1.25V}{0.025V} \text{ for 1.25V to 7.625V range}$$

$$x = \frac{V_{TH} - 0.1667V}{0.0033V} \text{ for 0.1667V to 1.0167V high-Z range}$$

where V_{TH} is the desired threshold voltage and x is the decimal code for the desired threshold (Table 4).

Table 2. IN1 Threshold Settings

REGISTER ADDRESS	EEPROM MEMORY ADDRESS	BIT RANGE	DESCRIPTION
00h	80h	[7:0]	IN1 undervoltage detector threshold (V1) (see equations in the *Inputs* section)
08h	88h	[0]	IN1 range selection. 0 = 2.5V to 13.2V range in 50mV increments. 1 = 1.25V to 7.625V range in 25mV increments.
09h	89h	[0]	Must be set to "0" for normal operation

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Table 3. IN2–IN7 Threshold Settings

REGISTER ADDRESS	EEPROM MEMORY ADDRESS	BIT RANGE	DESCRIPTION
01h	81h	[7:0]	IN2 undervoltage detector threshold (V2) (see equations in the *Inputs* section)
02h	82h	[7:0]	IN3 undervoltage detector threshold (V3) (see equations in the *Inputs* section)
03h	83h	[7:0]	IN4 undervoltage detector threshold (V4) (see equations in the *Inputs* section)
04h	84h	[7:0]	IN5 (MAX6889/MAX6890 only) undervoltage detector threshold (V5) (see equations in the *Inputs* section)
05h	85h	[7:0]	IN6 (MAX6889/MAX6890 only) undervoltage detector threshold (V6) (see equations in the *Inputs* section)
06h	86h	[7:0]	IN7 (MAX6889 only) undervoltage detector threshold (V7) (see equations in the *Inputs* section)
08h	88h	[1]	IN2 range selection, 0 = 1V to 5.5V range in 20mV increments, 1 = 0.5V to 3.05V range in 10mV increments
		[2]	IN3 range selection, 0 = 1V to 5.5V range in 20mV increments, 1 = 0.5V to 3.05V range in 10mV increments
		[3]	IN4 range selection, 0 = 1V to 5.5V range in 20mV increments, 1 = 0.5V to 3.05V range in 10mV increments
		[4]	IN5 (MAX6889/MAX6890 only) range selection, 0 = 1V to 5.5V range in 20mV increments, 1 = 0.5V to 3.05V range in 10mV increments
		[5]	IN6 (MAX6889/MAX6890 only) range selection, 0 = 1V to 5.5V range in 20mV increments, 1 = 0.5V to 3.05V range in 10mV increments
		[6]	IN7 (MAX6889 only) range selection, 0 = 1V to 5.5V range in 20mV increments, 1 = 0.5V to 3.05V range in 10mV increments
		[7]	Not used
09h	89h	[1]	IN2 input impedance. 0 = normal mode. 1 = high-Z mode, with a 0.1667V to 1.0167V range in 3.3mV increments.
		[2]	IN3 input impedance. 0 = normal mode. 1 = high-Z mode, with a 0.1667V to 1.0167V range in 3.3mV increments.
		[3]	IN4 input impedance. 0 = normal mode. 1 = high-Z mode, with a 0.1667V to 1.0167V range in 3.3mV increments.
		[4]	IN5 input impedance. 0 = normal mode. 1 = high-Z mode, with a 0.1667V to 1.0167V range in 3.3mV increments.
		[5]	IN6 input impedance. 0 = normal mode. 1 = high-Z mode, with a 0.1667V to 1.0167V range in 3.3mV increments.
		[6]	IN7 input impedance. 0 = normal mode. 1 = high-Z mode, with a 0.1667V to 1.0167V range in 3.3mV increments.

GPI1–GPI4

The GPI1–GPI4 (General-Purpose Input) programmable logic inputs control power-supply sequencing (programmable outputs), reset/interrupt signaling, and watchdog functions (see the *Configuring the Watchdog Timer* section). Configure GPI1–GPI4 for active-low or active-high logic (Table 5). GPI1–GPI4 internally pull down to GND through a 10µA current sink.

$\overline{MR}$

The manual reset ($\overline{MR}$) input initiates a reset condition. See Table 6 to program the PO_ outputs to assert when $\overline{MR}$ is low. All affected programmable outputs remain asserted (see the *Programmable Outputs* section) for their PO_ timeout periods after $\overline{MR}$ releases high. An internal 10µA current source pulls $\overline{MR}$ to DBP. Leave $\overline{MR}$ unconnected or connect to DBP if unused.

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Table 4. IN8 Threshold Settings

REGISTER ADDRESS	EEPROM MEMORY ADDRESS	BIT RANGE	DESCRIPTION
07h	87h	[7:0]	IN8 undervoltage detector threshold (V8) (see equations in the *Inputs* section)
08h	88h	[7]	IN8 range selection. 0 = 2.5V to 15.25V range in 50mV increments. 1 = 1.25V to 7.625V range in 25mV increments.
09h	89h	[7]	IN8 input impedance. 0 = normal mode. 1 = high-Z mode, with a 0.1667V to 1.0167V range in 3.3mV increments.

Table 5. GPI1–GPI4 Active Logic States

REGISTER ADDRESS	EEPROM ADDRESS	BIT RANGE	DESCRIPTION
28h	A8h	[0]	GPI1. 0 = active-low, 1 = active-high.
		[1]	GPI2. 0 = active-low, 1 = active-high.
		[2]	GPI3. 0 = active-low, 1 = active-high.
		[3]	GPI4 (MAX6889/MAX6890 only). 0 = active-low, 1 = active-high.

$\overline{MARGIN}$

$\overline{MARGIN}$ allows system-level testing while power supplies exceed the normal ranges. Driving $\overline{MARGIN}$ low forces the programmable outputs to hold the last state while system-level testing occurs. Leave $\overline{MARGIN}$ unconnected or connect to DBP if unused. An internal 10µA current source pulls $\overline{MARGIN}$ to DBP. The state of each programmable output does not change while $\overline{MARGIN}$ = GND. $\overline{MARGIN}$ overrides $\overline{MR}$ if both assert at the same time.

Programmable Outputs

The MAX6889 features ten programmable outputs, the MAX6890 features eight programmable outputs, and the MAX6891 features five programmable outputs. Selectable output stage configurations include: active-low or active-high, open drain, or weak pullup. During power-up, the programmable outputs pull to GND with an internal 10µA current sink for 1V < V_{CC} < V_{UVLO}. The programmable outputs remain in their active states until their respective PO timeout period expires, and all of the programmed conditions are met for each output. Any output programmed to depend on no condition always remains in its active state (Table 17). An output configured as active-high is considered asserted when that output is logic-high.

The voltage monitors generate fault signals (logical 0) to the MAX6889/MAX6890/MAX6891s' logic array when an input voltage is below the programmed undervoltage threshold. For example, the PO3 (Table 9) programmable output may depend on the IN1 undervoltage threshold, and the state of GPI1. Write "1"s to R10h[0] and R11h[1] to configure as indicated. IN1 must be above the undervoltage threshold (Table 2) and GPI1 must be inactive (Table 5) to be a logic "1," then PO3 deasserts. The logic state of PO3, in this example, is equivalent to the logical statement: "V1 · GPI1."

Registers 0Ah through 27h configure each of the programmable outputs. Programmable timing blocks set the PO_ timeout period from 25µs to 1600ms for each programmable output. See Table 17 to set the active state (active-high or active-low) for each programmable output and Tables 18 and 19 to select the output stage types, and PO_ timeout periods for each output. Each programmable output allows a different set of conditions to assert each output as shown in Tables 7–16.

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Table 6. Programmable Output Behavior and $\overline{MR}$

REGISTER ADDRESS	EEPROM MEMORY ADDRESS	BIT RANGE	DESCRIPTION
0Bh	8Bh	[5]	PO1. 0 = PO1 independent of $\overline{MR}$, 1 = PO1 asserts when $\overline{MR}$ = low.
0Eh	8Eh	[5]	PO2. 0 = PO2 independent of $\overline{MR}$, 1 = PO2 asserts when $\overline{MR}$ = low.
11h	91h	[5]	PO3. 0 = PO3 independent of $\overline{MR}$, 1 = PO3 asserts when $\overline{MR}$ = low.
14h	94h	[5]	PO4. 0 = PO4/PO2 independent of $\overline{MR}$, 1 = PO4 asserts when $\overline{MR}$ = low.
17h	97h	[5]	PO5. 0 = PO5 independent of $\overline{MR}$, 1 = PO5 asserts when $\overline{MR}$ = low.
1Ah	9Ah	[5]	PO6 (MAX6889/MAX6890 only). 0 = PO6 independent of $\overline{MR}$, 1 = PO6 asserts when $\overline{MR}$ = low.
1Dh	9Dh	[5]	PO7 (MAX6889/MAX6890 only). 0 = PO7 independent of $\overline{MR}$, 1 = PO7 asserts when $\overline{MR}$ = low.
20h	A0h	[5]	PO8 (MAX6889/MAX6890 only). 0 = PO8 independent of $\overline{MR}$, 1 = PO8 asserts when $\overline{MR}$ = low.
23h	A3h	[5]	PO9 (MAX6889 only). 0 = PO9 independent of $\overline{MR}$, 1 = PO9 asserts when $\overline{MR}$ = low.
26h	A6h	[5]	PO10 (MAX6889 only). 0 = PO10 independent of $\overline{MR}$, 1 = PO10 asserts when $\overline{MR}$ = low.

Table 7. PO1 Output Dependency

REGISTER ADDRESS	EEPROM MEMORY ADDRESS	BIT	OUTPUT ASSERTION CONDITIONS
0Ah	8Ah	[0]	1 = PO1 assertion depends on IN1 undervoltage threshold (Table 2)
		[1]	1 = PO1 assertion depends on IN2 undervoltage threshold (Table 3)
		[2]	1 = PO1 assertion depends on IN3 undervoltage threshold (Table 3)
		[3]	1 = PO1 assertion depends on IN4 undervoltage threshold (Table 3)
		[4]	1 = PO1 assertion depends on IN5 (MAX6889/MAX6890 only) undervoltage threshold (Table 3)
		[5]	1 = PO1 assertion depends on IN6 (MAX6889/MAX6890 only) undervoltage threshold (Table 3)
		[6]	1 = PO1 assertion depends on IN7 (MAX6890 only) undervoltage threshold (Table 3)
		[7]	1 = PO1 assertion depends on IN8 (MAX6890 only) undervoltage threshold (Table 4)
0Bh	8Bh	[0]	1 = PO1 assertion depends on watchdog (Table 20)
		[1]	1 = PO1 assertion depends on GPI1 (Table 5)
		[2]	1 = PO1 assertion depends on GPI2 (Table 5)
		[3]	1 = PO1 assertion depends on GPI3 (Table 5)
		[4]	1 = PO1 assertion depends on GPI4 (MAX6889/MAX6890 only) (Table 5)
		[5]	1 = PO1 asserts when $\overline{MR}$ = low (Table 6)
		[7:6]	Not used

Note: *Table 7 only applies to PO1. Write a "0" to a bit to make the PO1 output independent of the respective signal (IN_ thresholds, WD, GPI_, or $\overline{MR}$).*

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Table 8. PO2 Output Dependency

REGISTER ADDRESS	EEPROM MEMORY ADDRESS	BIT	OUTPUT ASSERTION CONDITIONS
0Dh	8Dh	[0]	1 = PO2 assertion depends on IN1 undervoltage threshold (Table 2)
		[1]	1 = PO2 assertion depends on IN2 undervoltage threshold (Table 3)
		[2]	1 = PO2 assertion depends on IN3 undervoltage threshold (Table 3)
		[3]	1 = PO2 assertion depends on IN4 undervoltage threshold (Table 3)
		[4]	1 = PO2 assertion depends on IN5 (MAX6889/MAX6890 only) undervoltage threshold (Table 3)
		[5]	1 = PO2 assertion depends on IN6 (MAX6889/MAX6890 only) undervoltage threshold (Table 3)
		[6]	1 = PO2 assertion depends on IN7 (MAX6890 only) undervoltage threshold (Table 3)
		[7]	1 = PO2 assertion depends on IN8 (MAX6890 only) undervoltage threshold (Table 4)
0Eh	8Eh	[0]	1 = PO2 assertion depends on watchdog (Table 20)
		[1]	1 = PO2 assertion depends on GPI1 (Table 5)
		[2]	1 = PO2 assertion depends on GPI2 (Table 5)
		[3]	1 = PO2 assertion depends on GPI3 (Table 5)
		[4]	1 = PO2 assertion depends on GPI4 (MAX6889/MAX6890 only) (Table 5)
		[5]	1 = PO2 asserts when $\overline{MR}$ = low (Table 6)
		[7:6]	Not used

Note: Table 8 only applies to PO2. Write a "0" to a bit to make the PO2 output independent of the respective signal (IN_ thresholds, WD, GPI_, or $\overline{MR}$).

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Table 9. PO3 Output Dependency

REGISTER ADDRESS	EEPROM MEMORY ADDRESS	BIT	OUTPUT ASSERTION CONDITIONS
10h	90h	[0]	1 = PO3 assertion depends on IN1 undervoltage threshold (Table 2)
		[1]	1 = PO3 assertion depends on IN2 undervoltage threshold (Table 3)
		[2]	1 = PO3 assertion depends on IN3 undervoltage threshold (Table 3)
		[3]	1 = PO3 assertion depends on IN4 undervoltage threshold (Table 3)
		[4]	1 = PO3 assertion depends on IN5 (MAX6889/MAX6890 only) undervoltage threshold (Table 3)
		[5]	1 = PO3 assertion depends on IN6 (MAX6889/MAX6890 only) undervoltage threshold (Table 3)
		[6]	1 = PO3 assertion depends on IN7 (MAX6890 only) undervoltage threshold (Table 3)
		[7]	1 = PO3 assertion depends on IN8 (MAX6890 only) undervoltage threshold (Table 4)
11h	11h	[0]	1 = PO3 assertion depends on watchdog (Table 20)
		[1]	1 = PO3 assertion depends on GPI1 (Table 5)
		[2]	1 = PO3 assertion depends on GPI2 (Table 5)
		[3]	1 = PO3 assertion depends on GPI3 (Table 5)
		[4]	1 = PO3 assertion depends on GPI4 (MAX6889/MAX6890 only) (Table 5)
		[5]	1 = PO3 asserts when $\overline{MR}$ = low (Table 6)
		[7:6]	Not used

Note: Table 9 only applies to PO3. Write a "0" to a bit to make the PO3 output independent of the respective signal (IN_ thresholds, WD, GPI_, or $\overline{MR}$).

Table 10. PO4 Output Dependency

REGISTER ADDRESS	EEPROM MEMORY ADDRESS	BIT	OUTPUT ASSERTION CONDITIONS
13h	93h	[0]	1 = PO4 assertion depends on IN1 undervoltage threshold (Table 2)
		[1]	1 = PO4 assertion depends on IN2 undervoltage threshold (Table 3)
		[2]	1 = PO4 assertion depends on IN3 undervoltage threshold (Table 3)
		[3]	1 = PO4 assertion depends on IN4 undervoltage threshold (Table 3)
		[4]	1 = PO4 assertion depends on IN5 (MAX6889/MAX6890 only) undervoltage threshold (Table 3)
		[5]	1 = PO4 assertion depends on IN6 (MAX6889/MAX6890 only) undervoltage threshold (Table 3)
		[6]	1 = PO4 assertion depends on IN7 (MAX6890 only) undervoltage threshold (Table 3)
		[7]	1 = PO4 assertion depends on IN8 (MAX6890 only) undervoltage threshold (Table 4)
14h	14h	[0]	1 = PO4 assertion depends on watchdog (Table 20)
		[1]	1 = PO4 assertion depends on GPI1 (Table 5)
		[2]	1 = PO4 assertion depends on GPI2 (Table 5)
		[3]	1 = PO4 assertion depends on GPI3 (Table 5)
		[4]	1 = PO4 assertion depends on GPI4 (MAX6889/MAX6890 only) (Table 5)
		[5]	1 = PO4 asserts when $\overline{MR}$ = low (Table 6)
		[7:6]	Not used

Note: *Table 10 only applies to PO4. Write a "0" to a bit to make the PO4 output independent of the respective signal (IN_ thresholds, WD, GPI_, or $\overline{MR}$).*

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Table 11. PO5 Output Dependency

REGISTER ADDRESS	EEPROM MEMORY ADDRESS	BIT	OUTPUT ASSERTION CONDITIONS
16h	96h	[0]	1 = PO5 assertion depends on IN1 undervoltage threshold (Table 2)
		[1]	1 = PO5 assertion depends on IN2 undervoltage threshold (Table 3)
		[2]	1 = PO5 assertion depends on IN3 undervoltage threshold (Table 3)
		[3]	1 = PO5 assertion depends on IN4 undervoltage threshold (Table 3)
		[4]	1 = PO5 assertion depends on IN5 (MAX6889/MAX6890 only) undervoltage threshold (Table 3)
		[5]	1 = PO5 assertion depends on IN6 (MAX6889/MAX6890 only) undervoltage threshold (Table 3)
		[6]	1 = PO5 assertion depends on IN7 (MAX6890 only) undervoltage threshold (Table 3)
		[7]	1 = PO5 assertion depends on IN8 (MAX6890 only) undervoltage threshold (Table 4)
17h	17h	[0]	1 = PO5 assertion depends on watchdog (Table 20)
		[1]	1 = PO5 assertion depends on GPI1 (Table 5)
		[2]	1 = PO5 assertion depends on GPI2 (Table 5)
		[3]	1 = PO5 assertion depends on GPI3 (Table 5)
		[4]	1 = PO5 assertion depends on GPI4 (MAX6889/MAX6890 only) (Table 5)
		[5]	1 = PO5 asserts when $\overline{MR}$ = low (Table 6)
		[7:6]	Not used

Note: *Table 11 only applies to PO5. Write a "0" to a bit to make the PO5 output independent of the respective signal (IN_ thresholds, WD, GPI_, or $\overline{MR}$).*

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Table 12. PO6 (MAX6889/MAX6890 Only) Output Dependency

REGISTER ADDRESS	EEPROM MEMORY ADDRESS	BIT	OUTPUT ASSERTION CONDITIONS
19h	99h	[0]	1 = PO6 assertion depends on IN1 undervoltage threshold (Table 2)
		[1]	1 = PO6 assertion depends on IN2 undervoltage threshold (Table 3)
		[2]	1 = PO6 assertion depends on IN3 undervoltage threshold (Table 3)
		[3]	1 = PO6 assertion depends on IN4 undervoltage threshold (Table 3)
		[4]	1 = PO6 assertion depends on IN5 undervoltage threshold (Table 3)
		[5]	1 = PO6 assertion depends on IN6 undervoltage threshold (Table 3)
		[6]	1 = PO6 assertion depends on IN7 (MAX6890 only) undervoltage threshold (Table 3)
		[7]	1 = PO6 assertion depends on IN8 (MAX6890 only) undervoltage threshold (Table 4)
1Ah	9Ah	[0]	1 = PO6 assertion depends on watchdog (Table 20)
		[1]	1 = PO6 assertion depends on GPI1 (Table 5)
		[2]	1 = PO6 assertion depends on GPI2 (Table 5)
		[3]	1 = PO6 assertion depends on GPI3 (Table 5)
		[4]	1 = PO6 assertion depends on GPI4 (Table 5)
		[5]	1 = PO4 asserts when $\overline{MR}$ = low (Table 6)
		[7:6]	Not used

Note: Table 12 only applies to PO6 (MAX6889/MAX6890 only). Write a "0" to a bit to make the PO6 output independent of the respective signal (IN_ thresholds, WD, GPI_, or $\overline{MR}$).

Table 13. PO7 (MAX6889/MAX6890 Only) Output Dependency

REGISTER ADDRESS	EEPROM MEMORY ADDRESS	BIT	OUTPUT ASSERTION CONDITIONS
1Ch	9Ch	[0]	1 = PO7 assertion depends on IN1 undervoltage threshold (Table 2)
		[1]	1 = PO7 assertion depends on IN2 undervoltage threshold (Table 3)
		[2]	1 = PO7 assertion depends on IN3 undervoltage threshold (Table 3)
		[3]	1 = PO7 assertion depends on IN4 undervoltage threshold (Table 3)
		[4]	1 = PO7 assertion depends on IN5 undervoltage threshold (Table 3)
		[5]	1 = PO7 assertion depends on IN6 undervoltage threshold (Table 3)
		[6]	1 = PO7 assertion depends on IN7 (MAX6890 only) undervoltage threshold (Table 3)
		[7]	1 = PO7 assertion depends on IN8 (MAX6890 only) undervoltage threshold (Table 4)
1Dh	9Dh	[0]	1 = PO7 assertion depends on watchdog (Table 20)
		[1]	1 = PO7 assertion depends on GPI1 (Table 5)
		[2]	1 = PO7 assertion depends on GPI2 (Table 5)
		[3]	1 = PO7 assertion depends on GPI3 (Table 5)
		[4]	1 = PO7 assertion depends on GPI4 (Table 5)
		[5]	1 = PO7 asserts when $\overline{MR}$ = low (Table 6)
		[7:6]	Not used

Note: Table 13 only applies to PO7 (MAX6889/MAX6890 only). Write a "0" to a bit to make the PO7 output independent of the respective signal (IN_ thresholds, WD, GPI_, or $\overline{MR}$).

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Table 14. PO8 (MAX6889/MAX6890 Only) Output Dependency

REGISTER ADDRESS	EEPROM MEMORY ADDRESS	BIT	OUTPUT ASSERTION CONDITIONS
1Fh	9Fh	[0]	1 = PO8 assertion depends on IN1 undervoltage threshold (Table 2)
		[1]	1 = PO8 assertion depends on IN2 undervoltage threshold (Table 3)
		[2]	1 = PO8 assertion depends on IN3 undervoltage threshold (Table 3)
		[3]	1 = PO8 assertion depends on IN4 undervoltage threshold (Table 3)
		[4]	1 = PO8 assertion depends on IN5 undervoltage threshold (Table 3)
		[5]	1 = PO8 assertion depends on IN6 undervoltage threshold (Table 3)
		[6]	1 = PO8 assertion depends on IN7 (MAX6890 only) undervoltage threshold (Table 3)
		[7]	1 = PO8 assertion depends on IN8 (MAX6890 only) undervoltage threshold (Table 4)
20h	A0h	[0]	1 = PO8 assertion depends on watchdog (Table 20)
		[1]	1 = PO8 assertion depends on GPI1 (Table 5)
		[2]	1 = PO8 assertion depends on GPI2 (Table 5)
		[3]	1 = PO8 assertion depends on GPI3 (Table 5)
		[4]	1 = PO8 assertion depends on GPI4 (Table 5)
		[5]	1 = PO8 asserts when $\overline{MR}$ = low (Table 6)
		[7:6]	Not used

Note: *Table 14 only applies to PO8 (MAX6889/MAX6890 only). Write a "0" to a bit to make the PO8 output independent of the respective signal (IN_ thresholds, WD, GPI_, or $\overline{MR}$).*

Table 15. PO9 (MAX6889 Only) Output Dependency

REGISTER ADDRESS	EEPROM MEMORY ADDRESS	BIT	OUTPUT ASSERTION CONDITIONS
22h	A2h	[0]	1 = PO9 assertion depends on IN1 undervoltage threshold (Table 2)
		[1]	1 = PO9 assertion depends on IN2 undervoltage threshold (Table 3)
		[2]	1 = PO9 arssertion depends on IN3 undervoltage threshold (Table 3)
		[3]	1 = PO9 assertion depends on IN4 undervoltage threshold (Table 3)
		[4]	1 = PO9 assertion depends on IN5 undervoltage threshold (Table 3)
		[5]	1 = PO9 assertion depends on IN6 undervoltage threshold (Table 3)
		[6]	1 = PO9 assertion depends on IN7 undervoltage threshold (Table 3)
		[7]	1 = PO9 assertion depends on IN8 undervoltage threshold (Table 4)
23h	A3h	[0]	1 = PO9 assertion depends on watchdog (Table 20)
		[1]	1 = PO9 assertion depends on GPI1 (Table 5)
		[2]	1 = PO9 assertion depends on GPI2 (Table 5)
		[3]	1 = PO9 assertion depends on GPI3 (Table 5)
		[4]	1 = PO9 assertion depends on GPI4 (Table 5)
		[5]	1 = PO9 asserts when $\overline{MR}$ = low (Table 6)
		[7:6]	Not used

Note: *Table 15 only applies to PO9 (MAX6889 only). Write a "0" to a bit to make the PO9 output independent of the respective signal (IN_ thresholds, WD, GPI_, or $\overline{MR}$).*

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Table 16. PO10 (MAX6889 Only) Output Dependency

REGISTER ADDRESS	EEPROM MEMORY ADDRESS	BIT	OUTPUT ASSERTION CONDITIONS
25h	A5h	[0]	1 = PO10 assertion depends on IN1 undervoltage threshold (Table 2)
		[1]	1 = PO10 assertion depends on IN2 undervoltage threshold (Table 3)
		[2]	1 = PO10 assertion depends on IN3 undervoltage threshold (Table 3)
		[3]	1 = PO10 assertion depends on IN4 undervoltage threshold (Table 3)
		[4]	1 = PO10 assertion depends on IN5 undervoltage threshold (Table 3)
		[5]	1 = PO10 assertion depends on IN6 undervoltage threshold (Table 3)
		[6]	1 = PO10 assertion depends on IN7 undervoltage threshold (Table 3)
		[7]	1 = PO10 assertion depends on IN8 undervoltage threshold (Table 4)
26h	A6h	[0]	1 = PO10 assertion depends on watchdog (Table 20)
		[1]	1 = PO10 assertion depends on GPI1 (Table 5)
		[2]	1 = PO10 assertion depends on GPI2 (Table 5)
		[3]	1 = PO10 assertion depends on GPI3 (Table 5)
		[4]	1 = PO10 assertion depends on GPI4 (Table 5)
		[5]	1 = PO10 asserts when $\overline{MR}$ = low (Table 6)
		[7:6]	Not used

Note: Table 16 only applies to PO10 (MAX6890 only). Write a "0" to a bit to make the PO10 output independent of the respective signal (IN_ thresholds, WD, GPI_, or $\overline{MR}$).

Table 17. Programmable Output Active States

REGISTER ADDRESS	EEPROM MEMORY ADDRESS	BIT RANGE	AFFECTED OUTPUT	DESCRIPTION
0Ch	8Ch	[1]	PO1	0 = active-low, 1 = active-high
0Fh	8Fh	[1]	PO2	0 = active-low, 1 = active-high
12h	92h	[1]	PO3	0 = active-low, 1 = active-high
15h	95h	[1]	PO4	0 = active-low, 1 = active-high
18h	98h	[1]	PO5	0 = active-low, 1 = active-high
1Bh	9Bh	[1]	PO6	MAX6889/MAX6890 only. 0 = active-low, 1 = active-high.
1Eh	9Eh	[1]	PO7	MAX6889/MAX6890 only. 0 = active-low, 1 = active-high.
21h	A1h	[1]	PO8	MAX6889/MAX6890 only. 0 = active-low, 1 = active-high.
24h	A4h	[1]	PO9	MAX6889 only. 0 = active-low, 1 = active-high.
27h	A7h	[1]	PO10	MAX6889 only. 0 = active-low, 1 = active-high.

Output Stage Configurations

Independently configure each programmable output as active-high or active-low (Table 17). Additionally, configure each programmable output as open drain or weak pullup (Table 18). Finally, set the PO_ timeout period for each programmable output (Table 19). The programmable outputs can sink up to 4mA.

Weak Pullup Output Configuration

The MAX6889/MAX6890/MAX6891s' programmable outputs have a pullup resistance (10kΩ, typ) connected to the internal 2.55V LDO output to provide weak pullup outputs.

Open-Drain Output Configuration

Connect an external pullup resistor from the programmable output to an external voltage when configured as an open-drain output. Open-drain configured outputs may be pulled up to 13.2V. Choose the pullup resistor depending on the number of devices connected to the open-drain output and the allowable current consumption. The open-drain output configuration allows wire-ORed connections, and provides flexibility in setting the pullup current.

Configuring the Watchdog Timer (Registers 29h–2Ah)

A watchdog timer monitors microprocessor software execution for a stalled condition and resets the microprocessor if it stalls. The output of the watchdog timer (one of the programmable outputs) connects to the reset input or a nonmaskable interrupt of the microprocessor.

Registers 29h–2Ah configure the watchdog functionality of the MAX6889/MAX6890/MAX6891. Program the watchdog timer to assert one or more programmable outputs (see Tables 7–16). Program the watchdog timer to reset on one of the GPI_ inputs, one of the programmable outputs, or a combination of one GPI_ input and one programmable output.

The watchdog timer features independent initial and normal watchdog timeout periods. The initial watchdog timeout period applies immediately after power-up, after a software reboot, after a reset event takes place, or after enabling the watchdog timer. The initial watchdog timeout period allows the microprocessor to per-form its initialization process. If no pulse occurs during the initial watchdog timeout period, the microprocessor is taking too long to initialize, indicating a potential problem.

The normal watchdog timeout period applies after the initial watchdog timeout period occurs. The normal watchdog timeout period monitors a pulsed output of the microprocessor that indicates when normal processor behavior occurs. If no pulse occurs during the normal watchdog timeout period, this indicates that the processor has stopped operating or is stuck in an infinite execution loop.

Register 2Ah programs the initial and normal watchdog timeout periods, and enables or disables the watchdog timer. See Tables 20 and 21 for a summary of the watchdog behavior.

Configuration Lock

Lock the configuration register bank and configuration EEPROM contents after initial programming by setting the lock bit high (see Table 22). Locking the configuration prevents write operations to all registers except the configuration lock register. Clear the lock bit to reconfigure the device.

Internal/External V_{CC} Power

The MAX6889/MAX6890/MAX6891 can generate an internal V_{CC}, or V_{CC} can be externally supplied (see Table 22). To internally generate V_{CC} from the highest voltage on IN1–IN5 set register 2Eh and EEPROM address AEh Bit[2] = 0. To use an externally supplied, always-on V_{CC} ensure register 2Eh and EEPROM address AEh Bit[2] =1 (see the *Powering the MAX6889/ MAX6890/MAX6891* section).

Write Disable

A unique write-disable feature protects the MAX6889/ MAX6890/MAX6891 from inadvertent user-EEPROM writes. As input voltages that power the serial interface, a microprocessor, or any other writing-devices fall, unintentional data may be written onto the data bus. The user-EEPROM write-disable function (see Table 23) ensures that unintentional data does not corrupt the MAX6889/MAX6890/MAX6891 EEPROM data.

Table 18. Programmable Output Stage Options

REGISTER ADDRESS	EEPROM MEMORY ADDRESS	BIT RANGE	AFFECTED OUTPUT	DESCRIPTION
0Ch	8Ch	[0]	PO1	0 = weak pullup, 1 = open drain
0Fh	8Fh	[0]	PO2	0 = weak pullup, 1 = open drain
12h	92h	[0]	PO3	0 = weak pullup, 1 = open drain
15h	95h	[0]	PO4	0 = weak pullup, 1 = open drain
18h	98h	[0]	PO5	0 = weak pullup, 1 = open drain
1Bh	9Bh	[0]	PO6	MAX6889/MAX6890 only. 0 = weak pullup, 1 = open drain.
1Eh	9Eh	[0]	PO7	MAX6889/MAX6890 only. 0 = weak pullup, 1 = open drain.
21h	A1h	[0]	PO8	MAX6889/MAX6890 only. 0 = weak pullup, 1 = open drain.
24h	A4h	[0]	PO9	MAX6889 only. 0 = weak pullup, 1 = open drain.
27h	A7h	[0]	PO10	MAX6889 only. 0 = weak pullup, 1 = open drain.

Table 19. PO_ Timeout Periods

REGISTER ADDRESS	EEPROM MEMORY ADDRESS	BIT RANGE	AFFECTED OUTPUTS	DESCRIPTION
0Ch	8Ch	[4:2]	PO1	
0Fh	8Fh	[4:2]	PO2	
12h	92h	[4:2]	PO3	
15h	95h	[4:2]	PO4	000 = 25µs
18h	98h	[4:2]	PO5	001 = 1.5625ms
1Bh	9Bh	[4:2]	PO6 (MAX6889/MAX6890)	010 = 6.25ms
1Eh	9Eh	[4:2]	PO7 (MAX6889/MAX6890)	011 = 25ms 100 = 50ms
21h	A1h	[4:2]	PO8 (MAX6889/MAX6890)	101 = 200ms
24h	A4h	[4:2]	PO9 (MAX6889 only)	110 = 400ms
27h	A7h	[4:2]	PO10 (MAX6889 only)	111 = 1600ms

Table 20. Watchdog Inputs

REGISTER ADDRESS	EEPROM MEMORY ADDRESS	BIT RANGE	DESCRIPTION
29h	A9h	[1:0]	Watchdog Input Selection: 00 = GPI1 input 01 = GPI2 input 10 = GPI3 input 11 = GPI4 input (MAX6889/MAX6890 only). Selects GPI3 on MAX6891.
		[5:2]	Watchdog Internal Input Selection: 0000 = PO1 0001 = PO2 0010 = PO3 0011 = PO4 0100 = PO5 0101 = PO6 (MAX6889/MAX6890 only) 0110 = PO7 (MAX6889/MAX6890 only) 0111 = PO8 (MAX6889/MAX6890 only) 1000 = PO9 (MAX6889 only) 1001 = PO10 (MAX6889 only) [1011] to [1111] = WD is not affected by PO_
		[7:6]	Watchdog Dependency on Inputs: 00 = Watchdog not dependent on any input 01 = Watchdog clear depends on selected GPI_ input only 01 = Watchdog clear depends on selected PO_ input only 11 = Watchdog clear depends on both selected GPI_ and PO_ inputs

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Table 21. Watchdog Timeout Period Selection

REGISTER ADDRESS	EEPROM MEMORY ADDRESS	BIT RANGE	DESCRIPTION
2Ah	AAh	[2:0]	Normal Watchdog Timeout Period: 000 = 6.25ms 001 = 25ms 010 = 100ms 011 = 400ms 100 = 1.6s 101 = 6.4s 110 = 25.6s 111 = 102.4s
		[5:3]	Initial Watchdog Timeout Period (immediately following power-up, reset event, or enabling watchdog): 000 = 6.25ms 001 = 25ms 010 = 100ms 011 = 400ms 100 = 1.6s 101 = 6.4s 110 = 25.6s 111 = 102.4s
		[6]	Watchdog Enable 0 = Disables watchdog timer 1 = Enables watchdog timer
		[7]	Not used

Table 22. Configuration Lock and Internal/External V_{CC} Power Register

REGISTER ADDRESS	EEPROM MEMORY ADDRESS	BIT RANGE	DESCRIPTION
2Eh	AEh	[0]	0 = Configuration unlocked 1 = Configuration locked
		[1]	Not used
		[2]	Internal/External V_{CC} Power: 0 = V_{CC} internally generated 1 = V_{CC} externally supplied
		[7:3]	Not used

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Table 23. Write Disable Register

REGISTER ADDRESS	EEPROM MEMORY ADDRESS	BIT RANGE	DESCRIPTION
2Ch	ACh	[0]	0 = Write is not disabled if PO1 asserts 1 = Write disabled if PO1 asserts
		[1]	0 = Write is not disabled if PO2 asserts 1 = Write disabled if PO2 asserts
		[2]	0 = Write is not disabled if PO3 asserts 1 = Write disabled if PO3 asserts
		[3]	0 = Write is not disabled if PO4 asserts 1 = Write disabled if PO4 asserts
		[4]	0 = Write is not disabled if PO5 asserts 1 = Write disabled if PO5 asserts
		[5]	0 = Write is not disabled if PO6 asserts 1 = Write disabled if PO6 asserts
		[6]	0 = Write is not disabled if PO7 asserts 1 = Write disabled if PO7 asserts
		[7]	0 = Write is not disabled if PO8 asserts 1 = Write disabled if PO8 asserts
2Dh	ADh	[0]	0 = Write is not disabled if PO9 asserts 1 = Write disabled if PO9 asserts
		[1]	0 = Write is not disabled if PO10 asserts 1 = Write disabled if PO10 asserts
		[7:2]	Not used

Configuring the MAX6889/MAX6890/MAX6891

The MAX6889/MAX6890/MAX6891 factory-default configuration sets all registers to 0h, except bits in Tables 17 and 18, which are set to 1h. Factory-default configuration sets all PO_'s as active-high, open drain (all outputs are high impedance until the device is configured by the user). Each device requires configuration before full power is applied to the system. To configure the MAX6889/MAX6890/MAX6891, first apply an input voltage to IN1, or one of IN2–IN5 or V$_{CC}$ (see the *Powering the MAX6889/MAX6890/MAX6891* section). V$_{IN1}$ > 4V, or one of V$_{IN2}$–V$_{IN5}$ or V$_{CC}$ > 2.7V to ensure device operation. Next, transmit data through the serial interface. Use the block write protocol to quickly configure the device. Write to the configuration registers first to ensure the device is configured properly. After completing the setup procedure, use the read word or block read protocol to read back the data from the configuration registers. Lastly, use the write byte or block write protocol to write this data to the EEPROM registers. After completing the EEPROM register configuration, apply full power to the system to begin normal operation. The nonvolatile EEPROM stores the latest configuration upon removal of power. Write 0s to all EEPROM registers to clear the memory.

Software Reboot
A software reboot allows the user to restore the EEPROM configuration to the volatile registers without cycling the power supplies. Use the send byte command with data byte C4h to initiate a software reboot. The 3ms (max) power-up delay also applies after a software reboot.

Configuration EEPROM
The configuration EEPROM addresses range from 80h to AEh. Write data to the configuration EEPROM to automatically set up the MAX6889/MAX6890/MAX6891 upon power-up. Data is transferred from the configuration EEPROM to the configuration registers when V$_{CC}$ exceeds UVLO during power-up or after a software

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reboot. After V_{CC} exceeds UVLO, an internal 1MHz clock starts after a 5µs delay, and data transfer begins. Data transfer disables access to the configuration registers and EEPROM. The data transfer from EEPROM to configuration registers takes 3ms (max). Read configuration EEPROM data at any time after power-up or software reboot. Write commands to the configuration EEPROM are allowed at any time after power-up or software reboot, unless the configuration lock bit is set (see Table 22). The maximum cycle time to write a single byte is 11ms (max).
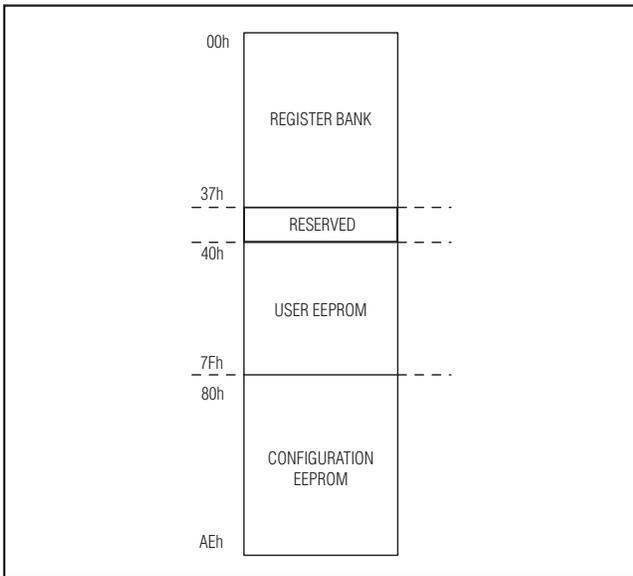

Figure 2. Memory Map

User EEPROM
The 512-bit, user-EEPROM addresses range from 40h to 7Fh (see Figure 2). Store software revision data, board revision data, and other data in these registers. The maximum cycle time to write a single byte is 11ms (max).

Configuration Register Bank and EEPROM
The configuration registers can be directly modified through the serial interface without modifying the EEPROM, after the power-up procedure terminates and the configuration EEPROM data has been loaded into the configuration register bank. Use the write byte or block write protocols to write directly to the configuration registers. Changes to the configuration registers take effect immediately and are lost upon power removal.

At device power-up, the register bank loads configuration data from the EEPROM. Configuration data may be directly altered in the register bank during application development, allowing maximum flexibility. Transfer the new configuration data byte-by-byte to the configuration EEPROM with the write byte protocol. The next device power-up or software reboot automatically loads the new configuration.

SMBus/I²C-Compatible Serial Interface
The MAX6889/MAX6890/MAX6891 feature an I²C/SMBus-compatible 2-wire serial interface consisting of a serial data line (SDA) and a serial clock line (SCL). SDA and SCL facilitate bidirectional communication between the MAX6889/MAX6890/MAX6891 and the master device at clock rates up to 400kHz. Figure 3 shows the 2-wire interface timing diagram. The MAX6889/MAX6890/MAX6891 are transmit/receive slave-only devices, relying upon a
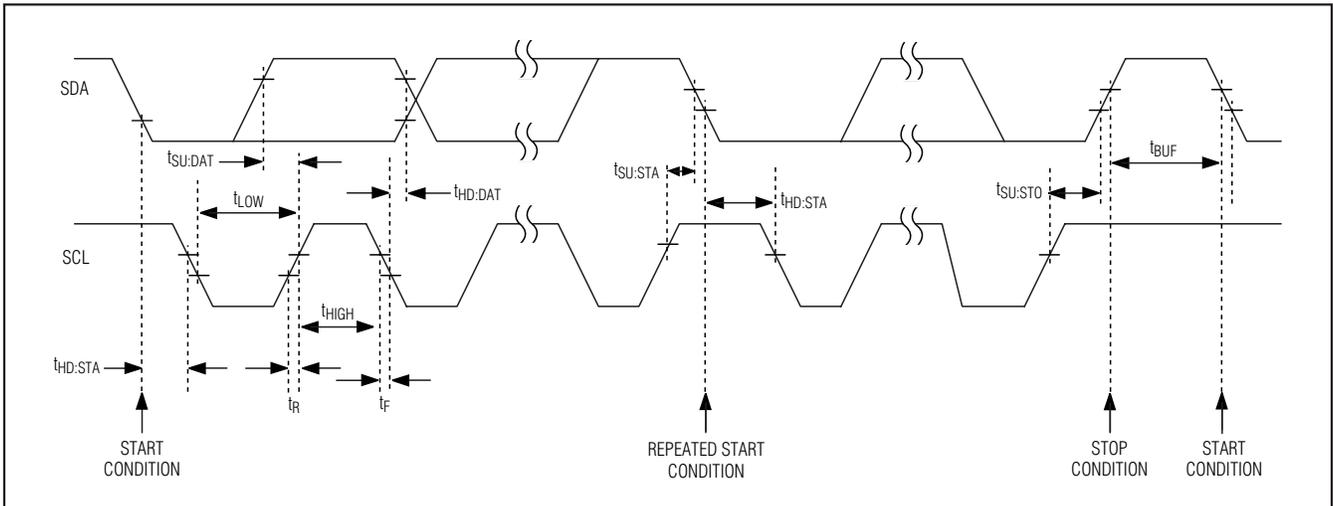

Figure 3. Serial-Interface Timing Details

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master device to generate a clock signal. The master device (typically a microcontroller) generates SCL and initiates data transfer on the bus.

A master device communicates to the MAX6889/MAX6890/MAX6891 by transmitting the proper address followed by command and/or data words. Each transmit sequence is framed by a START (S) or REPEATED START (SR) condition and a STOP (P) condition. Each word transmitted over the bus is 8 bits long and is always followed by an acknowledge pulse.

SCL is a logic input, while SDA is an open-drain input/output. SCL and SDA both require external pullup resistors to generate the logic-high voltage. Use 4.7kΩ resistors for most applications.

Bit Transfer

Each clock pulse transfers one data bit. The data on SDA must remain stable while SCL is high (Figure 4), otherwise the MAX6889/MAX6890/MAX6891 register a START or STOP condition (Figure 5) from the master. SDA and SCL idle high when the bus is not busy.

Start and Stop Conditions

A master device signals the beginning of a transmission with a START (S) condition (Figure 5) by transitioning SDA from high to low while SCL is high. The master device issues a STOP (P) condition (Figure 5) by transitioning SDA from low to high while SCL is high. A STOP condition frees the bus for another transmission. The bus remains active if a REPEATED START condition is generated, such as in the read byte or block read protocol (see Figure 8). Both SCL and SDA are high when the bus is not busy.

Early STOP Conditions

The MAX6889/MAX6890/MAX6891 recognize a STOP condition at any point during transmission except if a STOP condition occurs in the same high pulse as a START condition. This condition is not a legal I2C format. At least one clock pulse must separate any START and STOP condition.

Repeated START Conditions

A REPEATED START (SR) condition may indicate a change of data direction on the bus. Such a change occurs when a command word is required to initiate a read operation (see Figure 8). SR may also be used when the bus master is writing to several I2C devices and does not want to relinquish control of the bus. The MAX6889/MAX6890/MAX6891 serial interface supports continuous write operations with or without an SR condition separating them. Continuous read operations require SR conditions because of the change in direction of data flow.

Acknowledge

The acknowledge bit (ACK) is the 9th bit attached to any 8-bit data word. The receiving device always generates an ACK. The MAX6889/MAX6890/MAX6891 generate an ACK when receiving an address or data by pulling SDA low during the 9th clock period (Figure 6). When transmitting data, such as when the master device reads data back from the MAX6889/MAX6890/MAX6891, the MAX6889/MAX6890/MAX6891 wait for the master device to generate an ACK. Monitoring ACK allows for detection of unsuccessful data transfers. An unsuccessful data transfer occurs if the receiving device is busy or if a system fault has occurred. In the event of an unsuccessful
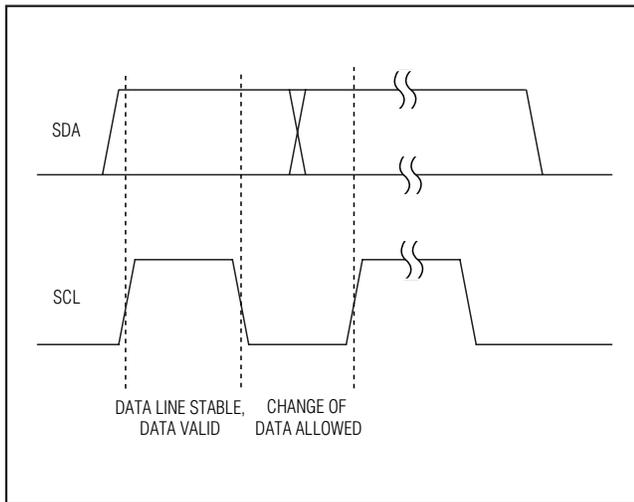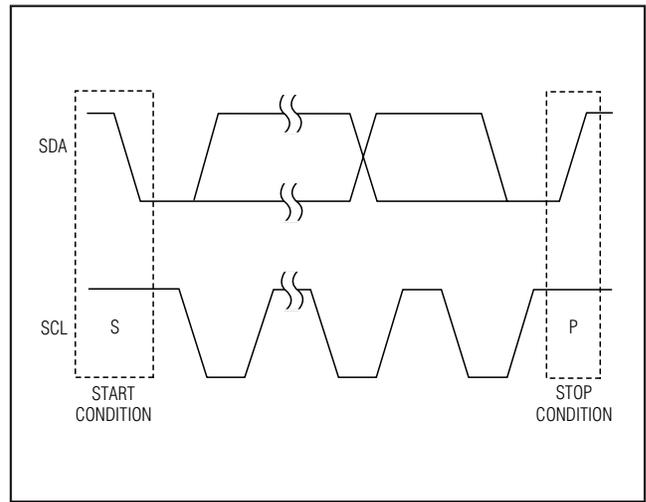

Figure 4. Bit Transfer

Figure 5. Start and Stop Conditions

MAX6889/MAX6890/MAX6891

data transfer, the bus master should reattempt communication at a later time. The MAX6889/MAX6890/MAX6891 generate a NACK after the command byte during a software reboot, while writing to the EEPROM, or when receiving an illegal memory address.

Slave Address

SA7 through SA4 represent the standard 2-wire interface address (1010) for devices with EEPROM. SA3 and SA2 correspond to the A1 and A0 address inputs of the MAX6889/MAX6890/MAX6891 (hardwired as logic-low or logic-high). SA0 is a read/write flag bit (0 = write, 1 = read).

The A0 and A1 address inputs allow up to four MAX6889/MAX6890 to connect to one bus, while the A0 address input allows up to two MAX6891s to connect to one bus. Connect A0 and A1 to GND or to the 2-wire serial-interface power supply (see Figure 7).

The MAX6889/MAX6890 slave address conforms to the following table:

SA7 (MSB)	SA6	SA5	SA4	SA3	SA2	SA1	SA0 (LSB)
1	0	1	0	A1	A0	X	R/$\overline{W}$

X = Don't Care

The MAX6891 slave address conforms to the following table:

SA7 (MSB)	SA6	SA5	SA4	SA3	SA2	SA1	SA0 (LSB)
1	0	1	0	0	A0	X	R/$\overline{W}$

X = Don't Care
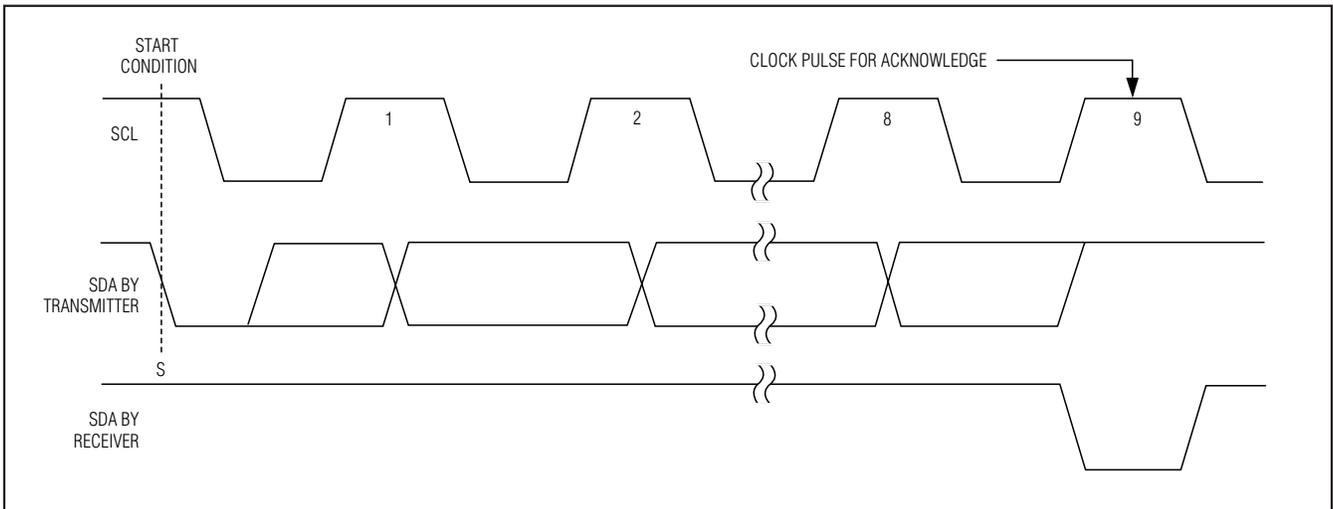
Figure 6. Acknowledge
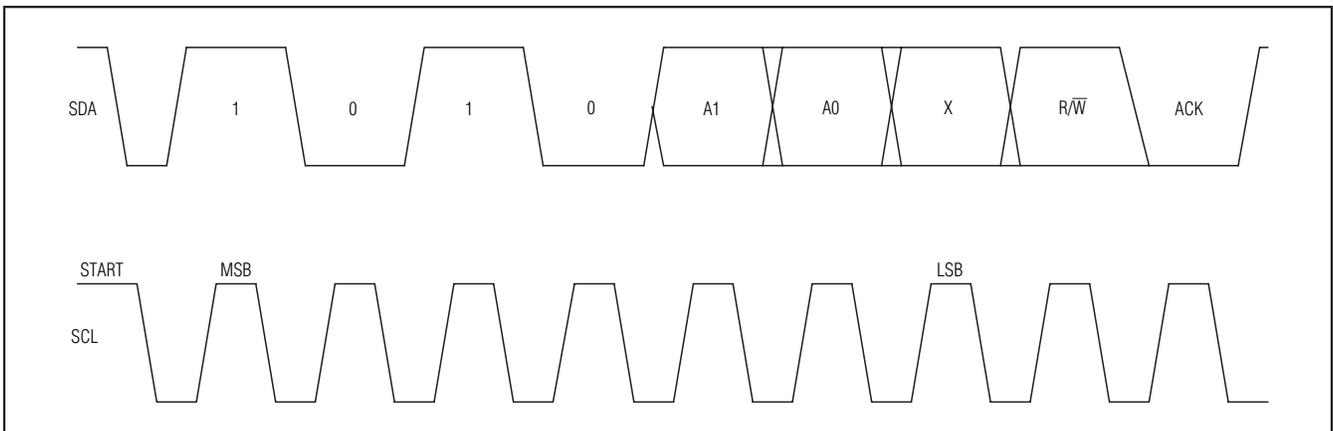
Figure 7. Slave Address

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Send Byte

The send byte protocol allows the master device to send one byte of data to the slave device (see Figure 8). The send byte presets a register pointer address for a subsequent read or write. The slave sends a NACK instead of an ACK if the master tries to send an address that is not allowed or if the device is writing data to EEPROM or is booting. If the master sends C0h, the data is ACK. This could be the start of the block write protocol, and the slave expects the following data bytes. If the master sends a Stop condition, the internal address pointer does not change. If the master sends C1h, this signifies that the block read protocol is expected, and a repeated Start condition should follow. The device reboots if the master sends C4h. The send byte procedure follows:

1) The master sends a Start condition.

2) The master sends the 7-bit slave address and a write bit (low).

3) The addressed slave asserts an ACK on SDA.

4) The master sends an 8-bit data byte.

5) The addressed slave asserts an ACK on SDA.

6) The master sends a Stop condition.

Write Byte

The write byte protocol allows the master device to write a single byte in the register bank or in the EEPROM (configuration or user) (see Figure 8). The Write Byte procedure follows:

1) The master sends a Start condition.

2) The master sends the 7-bit slave address and a write bit (low).

3) The addressed slave asserts an ACK on SDA.

4) The master sends an 8-bit command code.

5) The addressed slave asserts an ACK on SDA.

6) The master sends an 8-bit data byte.

7) The addressed slave asserts an ACK on SDA.

8) The master sends a Stop condition.

In order to write a single byte to the register bank, only the 8-bit command code and a single 8-bit data byte are sent. The command code must be in the range of 00h to 2Eh. The data byte is written to the register bank if the command code is valid. The slave generates a NACK at step 5 if the command code is invalid or any internal operations are ongoing.

In order to write a single byte of data to the user or configuration EEPROM, the 8-bit command code and a single 8-bit data byte are sent. The following 8-bit data byte is written to the addressed EEPROM location.

Block Write

The block write protocol allows the master device to write a block of data (1 to 16 bytes) to the EEPROM or to the register bank (see Figure 8). The destination address must already be set by the send byte protocol and the command code must be C0h. If the number of bytes to be written causes the address pointer to exceed 2Fh for the configuration register or B7h for the configuration EEPROM, the address pointer stops incrementing, overwriting the last memory address with the remaining bytes of data. Only the last data byte sent is stored in B7h (as 2Fh is read only and a write causes no change in the content). If the number of bytes to be written exceeds the address pointer 7Fh for the user EEPROM, the address pointer stops incrementing and continues writing exceeding data to the last address. Only the last data is actually written to 7Fh. The block write procedure follows:

1) The master sends a Start condition.

2) The master sends the 7-bit slave address and a write bit (low).

3) The addressed slave asserts an ACK on SDA.

4) The master sends the 8-bit command code for block write (C0h).

5) The addressed slave asserts an ACK on SDA.

6) The master sends the 8-bit byte count (1 to 16 bytes) N.

7) The addressed slave asserts an ACK on SDA.

8) The master sends 8 bits of data.

9) The addressed slave asserts an ACK on SDA.

10) Repeat steps 8 and 9 N – 1 times.

11) The master generates a Stop condition.

MAX6889/MAX6890/MAX6891

Read Byte

The read byte protocol allows the master device to read the register or an EEPROM location (user or configuration) content of the MAX6889/MAX6890/MAX6891 (see Figure 8). The read byte procedure follows:

1) The master sends a Start condition.
2) The master sends the 7-bit slave address and a write bit (low).
3) The addressed slave asserts an ACK on the data line.
4) The master sends 8 data bits.
5) The active slave asserts an ACK on the data line.
6) The master sends a repeated Start condition.
7) The master sends the 7-bit slave ID plus a read bit (high).
8) The addressed slave asserts an ACK on the data line.
9) The slave sends 8 data bits.
10) The master asserts a NACK on the data line
11) The master generates a Stop condition.

Note that once the read has been done, the internal pointer is increased by one, unless a memory boundary is hit.

If the device is busy or if the address is not an allowed one, the command code is NACKed and the internal address pointer is not altered. The master must then interrupt the communication issuing a STOP condition.

Block Read

The block read protocol allows the master device to read a block of 16 bytes from the EEPROM or register bank (see Figure 8). Read fewer than 16 bytes of data by issuing an early STOP condition from the master, or by generating a NACK with the master. Previous actions through the serial interface predetermines the first source address. It is suggested to use a send byte protocol, before the block read, to set the initial read address. The block read protocol is initiated with a command code of C1h. The block read procedure follows:

1) The master sends a Start condition.
2) The master sends the 7-bit slave address and a write bit (low).
3) The addressed slave asserts an ACK on SDA.

4) The master sends 8 bits of the block read command (C1h).
5) The slave asserts an ACK on SDA, unless busy.
6) The master generates a repeated Start condition.
7) The master sends the 7-bit slave address and a read bit (high).
8) The slave asserts an ACK on SDA.
9) The slave sends the 8-bit byte count (16).
10) The master asserts an ACK on SDA.
11) The slave sends 8 bits of data.
12) The master asserts an ACK on SDA.
13) Repeat steps 8 and 9 15 times.
14) The master generates a Stop condition.

Address Pointers

Use the send byte protocol to set the register address pointers before read and write operations. For the configuration registers, valid address pointers range from 00h to 2Fh. Register addresses outside of this range result in a NACK being issued from the MAX6889/MAX6890/MAX6891. When using the block write protocol, the address pointer automatically increments after each data byte, except when the address pointer is already at 2Fh. If the address pointer is already 2Fh, and more data bytes are being sent, these subsequent bytes overwrite address 2Fh repeatedly. No data will be left in 2Fh as this is a read-only address.

For the configuration EEPROM, valid address pointers range from 80h to B7h (even if they are only meaningful up to AEh). When using the block write protocol, the address pointer automatically increments after each data byte, except when the address pointer is already at B7h. If the address pointer is already B7h, and more data bytes are being sent, these subsequent bytes overwrite address B7h repeatedly, leaving only the last sent data byte stored at this register address.

For the user EEPROM, valid address pointers range from 40h to 7Fh. As for the configuration EEPROM, block write and block read protocols can also be used. The internal address pointer will auto-increment up to the user-EEPROM boundary 7Fh where the pointer will stop incrementing. When writing, only the last data written will be stored in 7Fh.

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SEND BYTE FORMAT

S	ADDRESS	$\overline{WR}$	ACK	DATA	ACK	P
	7 bits	0		8 bits		

Slave Address–equivalent to chip-select line of a 3-wire interface.

Data Byte–presets the internal address pointer or represents a command.

READ BYTE FORMAT

S	ADDRESS	$\overline{WR}$	ACK	DATA	ACK	SR	ADDRESS	$\overline{WR}$	ACK	DATA	$\overline{ACK}$	P
	7 bits	0		8 bits			7 bits	1		8 bits		

Slave Address–equivalent to chip-select line of a 3-wire interface.

Data Byte—presets the internal address pointer.

Slave Address—equivalent to chip-select line of a 3-wire interface.

Data Byte–data read from the preset register (or EEPROM) address.

WRITE BYTE FORMAT

S	ADDRESS	$\overline{WR}$	ACK	COMMAND	ACK	DATA	ACK	P
	7 bits	0		8 bits		8 bits		

Slave Address–equivalent to chip-select line of a 3-wire interface.

Command Byte–selects register EEPROM location you are writing to.

Data Byte–data goes into the register (or EEPROM location) set by the command byte.

BLOCK WRITE FORMAT

S	ADDRESS	$\overline{WR}$	ACK	COMMAND	ACK	BYTE COUNT= N	ACK	DATA BYTE 1	ACK	DATA BYTE ...	ACK	DATA BYTE N	ACK	P
	7 bits	0		C0h		8 bits		8 bits		8 bits		8 bits		

Slave Address–equivalent to chip-select line of a 3-wire interface.

Command Byte–prepares device for block write operation.

Data Byte–first data goes into the address preset with a previous "Set Address" and the following data in the following locations.

BLOCK READ FORMAT

S	ADDRESS	$\overline{WR}$	ACK	COMMAND	ACK	SR	ADDRESS	$\overline{WR}$	ACK	BYTE COUNT = N	ACK	DATA BYTE 1	ACK	DATA BYTE ...	ACK	DATA BYTE N	ACK	P
	7 bits	0		C1h			7 bits	1		8 bits		8 bits		8 bits		8 bits		

Slave Address–equivalent to chip-select line of a 3-wire interface.

Command Byte–prepares device for block operation.

Slave Address–equivalent to chip-select line of a 3-wire interface.

Data Byte–data comes from the address set by a previous "send byte".

S = Start condition.
P = Stop condition.
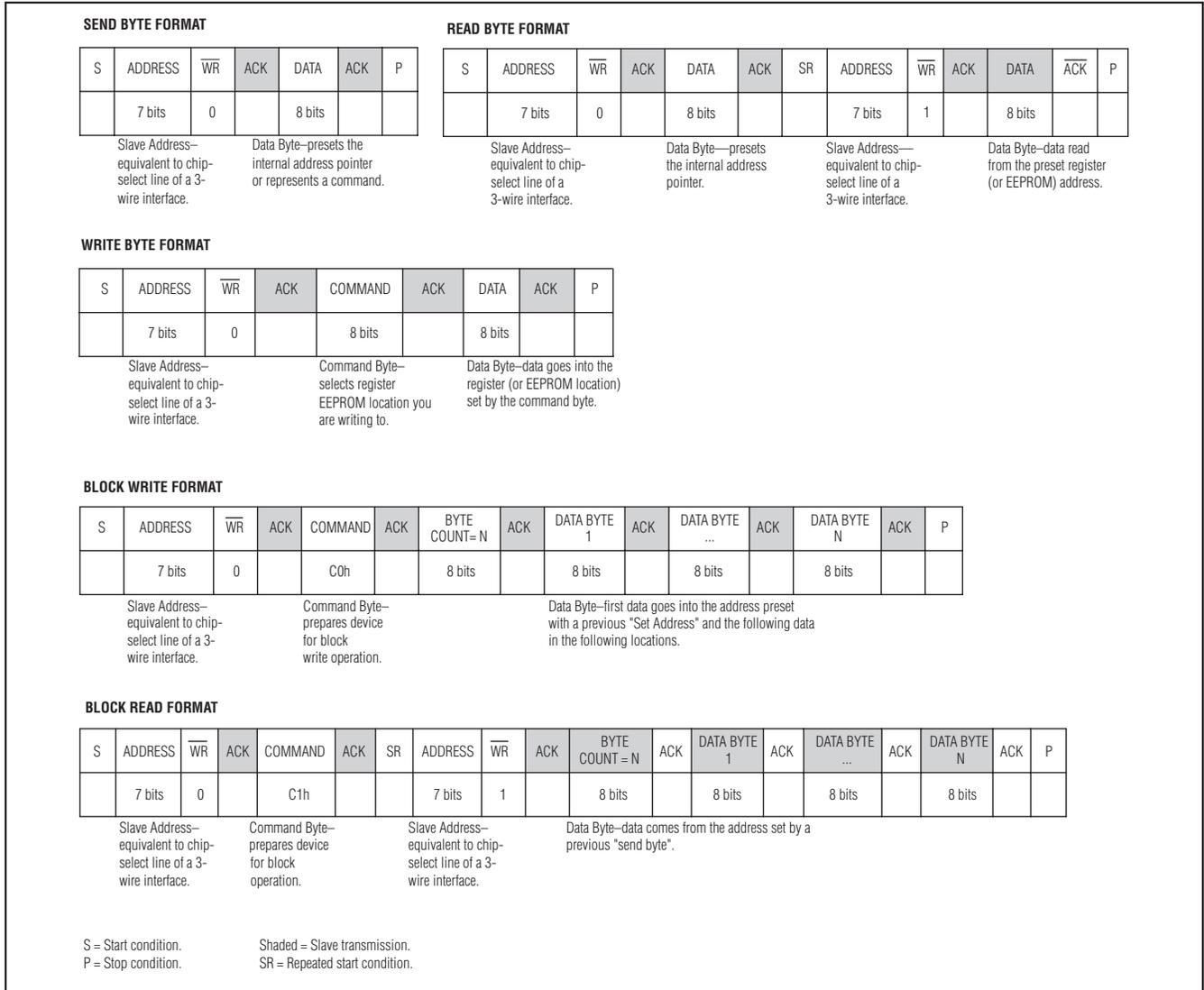Shaded = Slave transmission.
SR = Repeated start condition.

Figure 8. SMBus/I²C Protocols

_____Applications Information

Configuration Download at Power-up

The configuration of the MAX6889/MAX6890/MAX6891 (undervoltage thresholds, PO_ timeout periods, watchdog behavior, programmable output conditions and configurations, etc.) depends on the contents of the EEPROM. The EEPROM is comprised of buffered latches that store the configuration. The local volatile memory latches lose their contents at power-down. Therefore, at power-up, the device configuration must be restored by downloading the contents of the EEPROM (non-volatile memory) to the local latches. This download occurs in a number of steps:

1) Programmable outputs go high impedance with no power applied to the device.

2) When V_{CC} exceeds 1V, all programmable outputs are weakly pulled to GND through a 10µA current sink.

3) When V_{CC} exceeds UVLO, the configuration EEPROM starts to download its contents to the volatile configuration registers. The programmable outputs assume their programmed conditional output state when V_{CC} exceeds UVLO.

4) Any attempt to communicate with the device prior to this download completion results in a NACK being issued from the MAX6889/MAX6890/MAX6891.

Forcing Programmable Outputs High During Power-up

A weak, 10µA pulldown current holds all programmable outputs low during power-up until V_{CC} exceeds the undervoltage-lockout (UVLO) threshold. Applications requiring a guaranteed high programmable output for V_{CC} down to GND require external pullup resistors to maintain the logic state until V_{CC} exceeds UVLO. Use 20kΩ resistors for most applications.

Uses for General-Purpose Inputs (GPI_)

Watchdog Timer

Program GPI_ as an input to the watchdog timer in the MAX6889/MAX6890/MAX6891. The GPI_ input must toggle within the watchdog timeout period; otherwise any programmable output dependent on the watchdog timer will assert.

Additional Manual Reset Functions

The programmable outputs allow a set of conditions to assert the output. Program the set of conditions to depend on one of the GPI_ inputs. Any output that depends on GPI_ asserts when GPI_ is held in its active state, effectively acting as a manual reset input.

Other Fault Signals from µC

Connect a general-purpose output from a µC to one of the GPI_ inputs to allow interrupts to assert any output of the MAX6889/MAX6890/MAX6891. Configure one of the programmable outputs to assert on whichever GPI_ input connects to the general-purpose output of the µC.

Layout and Bypassing

For better noise immunity, bypass each of the voltage detector inputs to GND with 0.1µF capacitors installed as close to the device as possible. Bypass V_{CC} and DBP to GND with 1µF capacitors installed as close to the device as possible. V_{CC} (when not externally supplied) and DBP are internally generated voltages and should not be used to supply power to external circuitry.

Configuration Latency Period

A delay of less than 5µs occurs between writing to the configuration registers and the time when these changes actually take place, unless when changing one of the voltage detector's thresholds. Changing a voltage detector threshold typically takes 150µs. When changing EEPROM contents, a software reboot or cycling of power is required for these changes to transfer to volatile memory.

Chip Information

PROCESS: BiCMOS

Register Map

REGISTER ADDRESS	EEPROM MEMORY ADDRESS	READ/ WRITE	DESCRIPTION
00h	80h	R/W	IN1 undervoltage detector threshold (Table 2)
01h	81h	R/W	IN2 undervoltage detector threshold (Table 3)
02h	82h	R/W	IN3 undervoltage detector threshold (Table 3)
03h	83h	R/W	IN4 undervoltage detector threshold (Table 3)
04h	84h	R/W	IN5 undervoltage detector threshold (MAX6889/MAX6890 only) (Table 3)
05h	85h	R/W	IN6 undervoltage detector threshold (MAX6889/MAX6890 only) (Table 3)
06h	86h	R/W	IN7 undervoltage detector threshold (MAX6889 only) (Table 3)
07h	87h	R/W	IN8 undervoltage detector threshold (MAX6889 only) (Table 4)
08h	88h	R/W	Threshold range selection (Tables 2, 3, and 4)
09h	89h	R/W	High-Z mode selection (Tables 2, 3, and 4)
0Ah	8Ah	R/W	PO1 input selection (Table 7)
0Bh	8Bh	R/W	PO1 input selection (Table 7)
0Ch	8Ch	R/W	PO1 timeout period, programmable output polarity, and output type selection (Tables 17, 18, and 19)
0Dh	8Dh	R/W	PO2 input selection (Table 8)
0Eh	8Eh	R/W	PO2 input selection (Table 8)

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Register Map (continued)

REGISTER ADDRESS	EEPROM MEMORY ADDRESS	READ/WRITE	DESCRIPTION
0Fh	8Fh	R/W	PO2 timeout period and output type selection (Tables 17, 18, and 19)
10h	90h	R/W	PO3 input selection (Table 9)
11h	91h	R/W	PO3 input selection (Table 9)
12h	92h	R/W	PO3 timeout period and output type selection (Tables 17, 18, and 19)
13h	93h	R/W	PO4 input selection (Table 10)
14h	94h	R/W	PO4 input selection (Table 10)
15h	95h	R/W	PO4 timeout period and output type selection (Tables 17, 18, and 19)
16h	96h	R/W	PO5 input selection (Table 11)
17h	97h	R/W	PO5 input selection (Table 11)
18h	98h	R/W	PO5 timeout period and output type selection (Tables 17, 18, and 19)
19h	99h	R/W	PO6 (MAX6889/MAX6890) input selection (Table 12)
1Ah	9Ah	R/W	PO6 (MAX6889/MAX6890) input selection (Table 12)
1Bh	9Bh	R/W	PO6 (MAX6889/MAX6890) timeout period and output type selection (Tables 17, 18, and 19)
1Ch	9Ch	R/W	PO7 (MAX6889/MAX6890) input selection (Table 13)
1Dh	9Dh	R/W	PO7 (MAX6889/MAX6890) input selection (Table 13)
1Eh	9Eh	R/W	PO7 (MAX6889/MAX6890) timeout period and output type selection (Tables 17, 18, and 19)
1Fh	9Fh	R/W	PO8 (MAX6889/MAX6890) input selection (Table 14)
20h	A0h	R/W	PO8 (MAX6889/MAX6890) input selection (Table 14)
21h	A1h	R/W	PO8 (MAX6889/MAX6890) timeout period and output type selection (Tables 17, 18, and 19)
22h	A2h	R/W	PO9 (MAX6889 only) input selection (Table 15)
23h	A3h	R/W	PO9 (MAX6889 only) input selection (Table 15)
24h	A4h	R/W	PO9 (MAX6889 only) timeout period and output type selection (Tables 17, 18, and 19)
25h	A5h	R/W	PO10 (MAX6889 only) input selection (Table 16)
26h	A6h	R/W	PO10 (MAX6889 only) input selection (Table 16)
27h	A7h	R/W	PO10 (MAX6889 only) timeout period and output type selection (Tables 17, 18, and 19)
28h	A8h	R/W	GPI_ input polarity selection
29h	A9h	R/W	WD input selection and clear dependency (Table 20)
2Ah	AAh	R/W	WD initial and normal timeout duration and disable (Table 21)
2Bh	ABh	—	Reserved. Should not be overwritten.
2Ch	ACh	R/W	User EEPROM write disable (Table 23)
2Dh	ADh	R/W	User EEPROM write disable (Table 23)
2Eh	AEh	R/W	Configuration lock and internal/external V_{CC} power (Table 22)

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MAX6889/MAX6890/MAX6891

TOP VIEW

MAX6889 (5mm x 5mm THIN QFN)

Top pins (left to right): PO1 (32), N.C. (31), IN1 (30), IN2 (29), IN3 (28), IN4 (27), IN5 (26), IN6 (25)

Left pins (top to bottom): PO2 (1), PO3 (2), PO4 (3), GND (4), PO5 (5), PO6 (6), PO7 (7), PO8 (8)

Right pins (top to bottom): IN7 (24), IN8 (23), DBP (22), V_{CC} (21), GPI1 (20), GPI2 (19), GPI3 (18), GPI4 (17)

Bottom pins (left to right): PO9 (9), PO10 (10), MARGIN (11), $\overline{MR}$ (12), SDA (13), SCL (14), A0 (15), A1 (16)

*EXPOSED PAD

(5mm x 5mm THIN QFN)

*EXPOSED PAD INTERNALLY CONNECTED TO GND.

TOP VIEW

MAX6890 (5mm x 5mm THIN QFN)

Top pins (left to right): PO1 (28), N.C. (27), IN1 (26), IN2 (25), IN3 (24), IN4 (23), IN5 (22)

Left pins (top to bottom): PO2 (1), PO3 (2), PO4 (3), GND (4), PO5 (5), PO6 (6), PO7 (7)

Right pins (top to bottom): IN6 (21), DBP (20), V_{CC} (19), GPI1 (18), GPI2 (17), GPI3 (16), GPI4 (15)

Bottom pins (left to right): PO8 (8), MARGIN (9), $\overline{MR}$ (10), SDA (11), SCL (12), A0 (13), A1 (14)

*EXPOSED PAD

(5mm x 5mm THIN QFN)

*EXPOSED PAD INTERNALLY CONNECTED TO GND.

TOP VIEW

MAX6891 (5mm x 5mm THIN QFN)

Top pins (left to right): PO1 (20), IN1 (19), IN2 (18), IN3 (17), IN4 (16)

Left pins (top to bottom): PO2 (1), PO3 (2), PO4 (3), GND (4), PO5 (5)

Right pins (top to bottom): DBP (15), V_{CC} (14), GPI1 (13), GPI2 (12), GPI3 (11)

Bottom pins (left to right): MARGIN (6), $\overline{MR}$ (7), SDA (8), SCL (9), A0 (10)

*EXPOSED PAD

(5mm x 5mm THIN QFN)

*EXPOSED PAD INTERNALLY CONNECTED TO GND.

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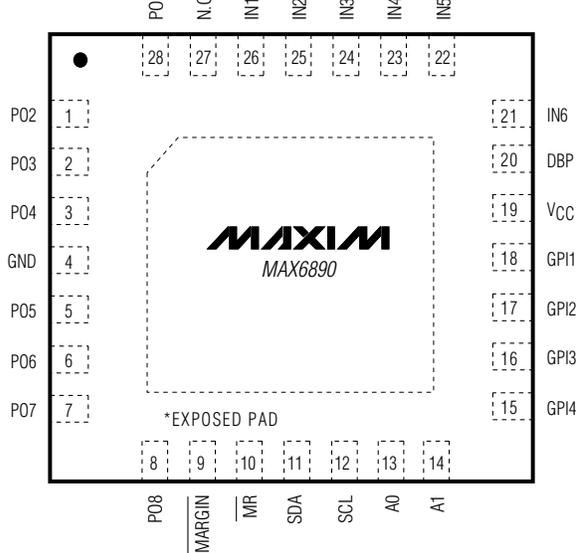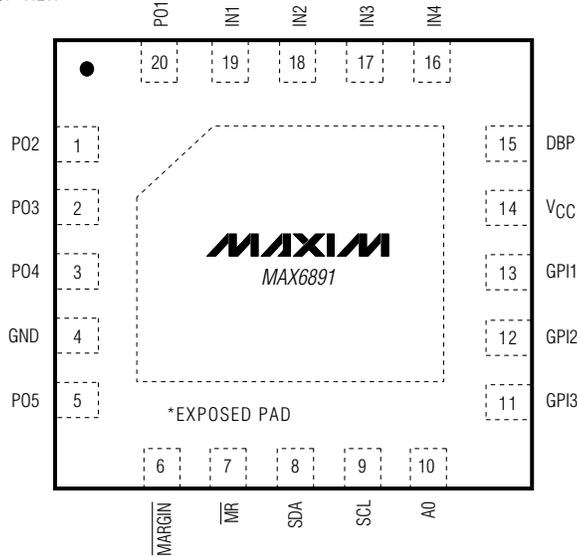
Typical Operating Circuit
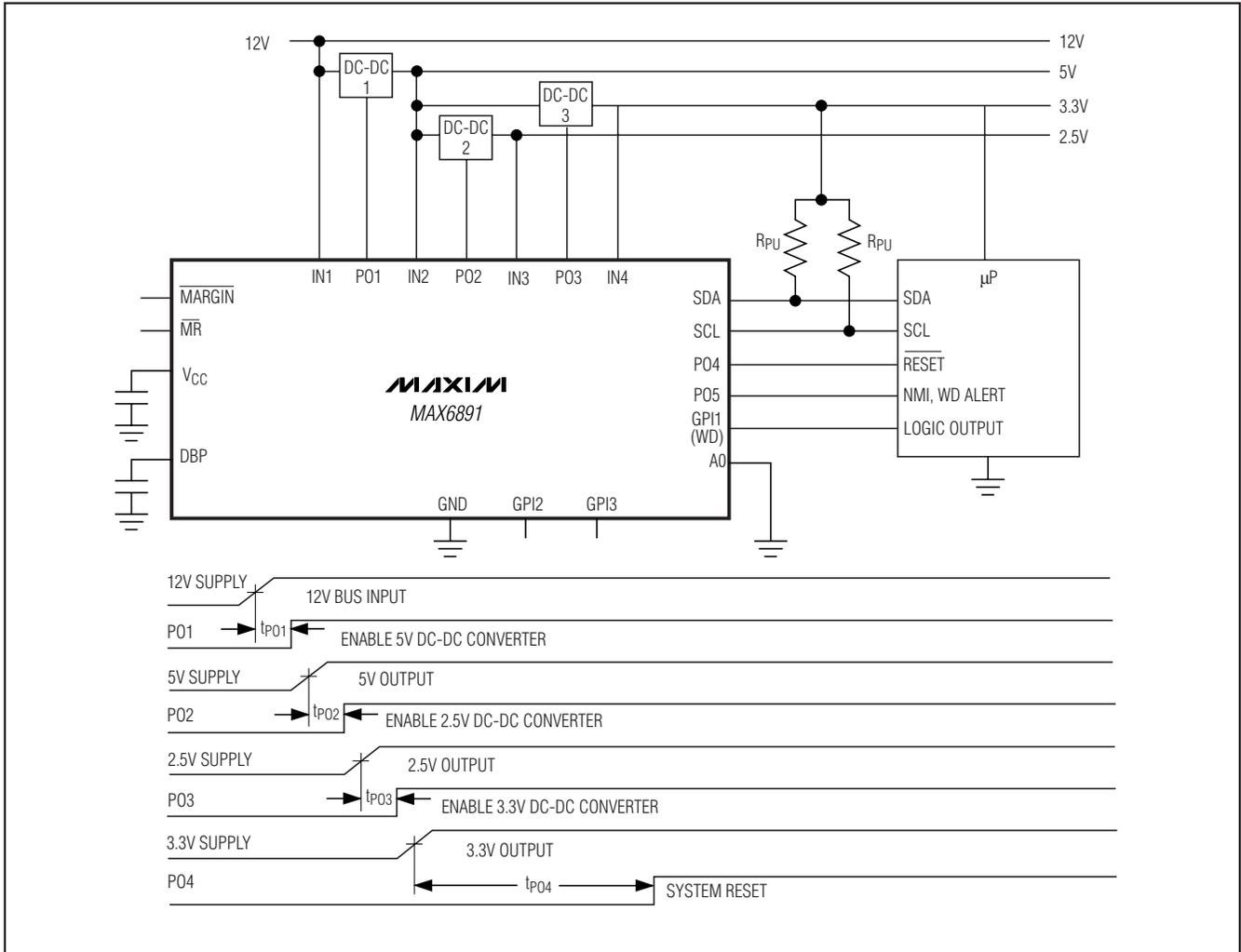
Package Information

For the latest package outline information and land patterns, go to **www.maxim-ic.com/packages**.

PACKAGE TYPE	PACKAGE CODE	DOCUMENT NO.
20 TQFN	T2055-5	**21-0140**
28 TQFN	T2855-8	**21-0140**
32 TQFN	T3255-4	**21-0140**

MAX6889/MAX6890/MAX6891

EEPROM-Programmable, Octal/Hex/Quad, Power-Supply Sequencers/Supervisors

**Revision History**

REVISION NUMBER	REVISION DATE	DESCRIPTION	PAGES CHANGED
0	2/05	Initial release	—
1	9/08	Added specifications to _Electrical Characteristics_.	4

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